

SBS v1.1-Compliant Gas Gauge IC

Check for Samples: [bq2060A](#)

FEATURES

- Provides Accurate Measurement of Available Charge in NiCd, NiMH, Li-Ion, and Lead-Acid Batteries
- Supports SBS Smart Battery Data Specification v1.1
- Supports the 2-Wire SMBus v1.1 Interface With PEC or 1-Wire HDQ16
- Reports Individual Cell Voltages
- Monitors and Provides Control to Charge and Discharge FETs in Li-Ion Protection Circuit
- Provides 15-Bit Resolution for Voltage, Temperature, and Current Measurements
- Measures Charge Flow Using a V-to-F Converter With Offset of Less Than 16 μ V After Calibration
- Consumes Less Than 0.5 mW Operating
- Drives a 4- or 5-Segment LED Display for Remaining Capacity Indication
- 28-Pin 150-Mil (3,8-mm) SSOP

DESCRIPTION

The bq2060A SBS-compliant gas gauge IC for battery pack or in-system installation maintains an accurate record of available charge in rechargeable batteries. The bq2060A monitors capacity and other critical battery parameters for NiCd, NiMH, Li-ion, and lead-acid chemistries. The bq2060A uses a voltage-to-frequency converter with automatic offset error correction for charge and discharge counting. For voltage, temperature, and current reporting, the bq2060A uses an A-to-D converter. The onboard ADC also monitors individual cell voltages in a Li-ion battery pack and allows the bq2060A to generate control signals that may be used with a pack supervisor to enhance pack safety.

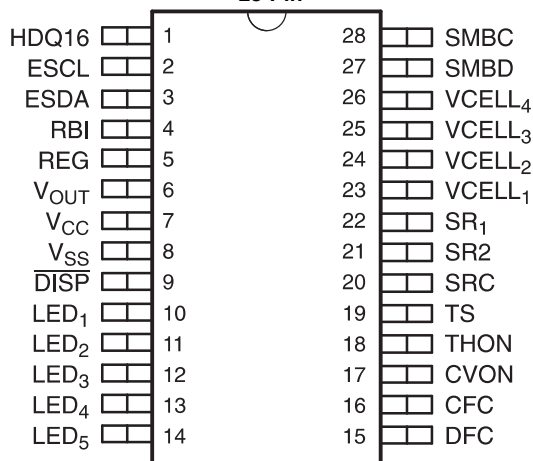
The bq2060A supports the smart battery data (SBDa) commands and charge-control functions. It communicates data using the system management bus (SMBus) 2-wire protocol or the Benchmark 1-wire HDQ16 protocol. The data available include the remaining battery capacity, temperature, voltage, current, and remaining run-time predictions. The bq2060A provides LED drivers and a pushbutton input to depict remaining battery capacity from full to empty in 20% or 25% increments with a 4- or 5-segment display.

The bq2060A works with an external EEPROM. The EEPROM stores the configuration information for the bq2060A, such as battery chemistry, self-discharge rate, rate compensation factors, measurement calibration, and design voltage and capacity. The bq2060A uses the programmable self-discharge rate and other compensation factors stored in the EEPROM to accurately adjust remaining capacity for use and standby conditions based on time, rate, and temperature. The bq2060A also automatically calibrates or learns the true battery capacity in the course of a discharge cycle from near-full to near-empty levels.

The REG output regulates the operating voltage for the bq2060A from the battery cell stack using an external JFET.

PIN CONNECTIONS

150-Mil (3,8-mm) SSOP
28-Pin



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

Pin Descriptions

PIN		DESCRIPTION
NAME	NUMBER	
HDQ16	1	Serial communication input/output. Open-drain bidirectional communications port
ESCL	2	Serial memory clock. Output to clock the data transfer between the bq2060A and the external nonvolatile configuration memory
ESDA	3	Serial memory data and address. Bidirectional pin used to transfer address and data to and from the bq2060A and the external nonvolatile configuration memory.
RBI	4	Register backup input. Input that provides backup potential to the bq2060A registers during periods of low operating voltage. RBI accepts a storage capacitor or a battery input.
REG	5	Regulator output. Output to control an n-JFET for VCC regulation to the bq2060A from the battery potential
V _{OUT}	6	EEPROM supply output. Output that supplies power to the external EEPROM configuration memory
V _{CC}	7	Supply voltage input
V _{SS}	8	Ground
DISP	9	Display control input. Input that controls the LED drivers LED ₁ –LED ₅
LED ₁ –LED ₅	10–14	LED display segment outputs. Outputs that each may drive an external LED
DFC	15	Discharge FET control. Output to control the discharge FET in the Li-ion pack protection circuitry
CFC	16	Charge FET control output. Output to control the charge FET in the Li-ion pack protection circuitry
CVON	17	Cell voltage divider control output. Output control for external FETs to connect the cells to the external voltage dividers during cell voltage measurements
THON	18	Thermistor bias control. Output control for external FETs to connect the thermistor bias resistor during a temperature measurement
TS	19	Thermistor voltage input. Input connection for a thermistor to monitor temperature
SRC	20	Current sense input. Input to monitor instantaneous current
SR ₁ –SR ₂	21–22	Charge-flow sense resistor inputs. Input connections for a small value sense resistor to monitor the battery charge and discharge current flow
VCELL ₁ –VCELL ₄	23–26	Single-cell voltage inputs. Inputs that monitor the series element cell voltages
SMBD	27	SMBus data. Open-drain bidirectional pin used to transfer address and data to and from the bq2060A
SMBC	28	SMBus clock. Open-drain bidirectional pin used to clock the data transfer to and from the bq2060A

ORDERING INFORMATION

bq2060A-E619 DBQ

Tape and Reel

blank= tubes

R = tape and reel

Package Option:

DBQ = 28-pin SSOP

Device

bq2060A SBS v1.1-Compliant Gas Gauge IC

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS

		MIN	MAX	UNIT	NOTES
Supply voltage, V_{CC}	Relative to V_{SS}	-0.3	6	V	
Input Voltage, V_{IN}	HDQ16, SMBC, SMBD relative to V_{SS}	-0.3	6	V	
	All other pins	$V_{SS} - 0.3$ to $V_{CC} + 0.3$		V	
Operating temperature, T_{OPR}		-20	70	°C	Commercial
Junction temperature, T_J		-40	125	°C	

DC ELECTRICAL CHARACTERISTICS

 $V_{CC} = 2.7\text{ V to }3.7\text{ V}$, $T_{OPR} = -20^{\circ}\text{C to }70^{\circ}\text{C}$, unless otherwise noted

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{CC}	Supply voltage		2.7	3.3	3.7	V
I_{CC}	Operating current	V_{OUT} inactive		180	235	μA
I_{SLP}	Low-power storage mode current	$1.5\text{ V} < V_{CC} < 3.7\text{ V}$		5	10	μA
I_{LVOUT}	V_{OUT} leakage current	V_{OUT} inactive	-0.2		0.2	μA
I_{VOUT}	V_{OUT} source current	V_{OUT} active, $V_{CC} - 0.6\text{ V}$	-5			mA
V_{OLS}	Output voltage low: LED1–LED5, CFC,DFC	$I_{OLS} = 5\text{ mA}$			0.4	V
	Output voltage low: THON, CVON	$I_{OLS} = 5\text{ mA}$			0.36	V
V_{IL}	Input voltage low DISP		-0.3		0.8	V
V_{IH}	Input voltage high DISP		2	$V_{CC} + 0.3$		V
V_{OL}	Output voltage low SMBC, SMBD, HDQ16, ESCL, ESDA	$I_{OL} = 1\text{ mA}$			0.4	V
V_{ILS}	Input voltage low SMBC, SMBD, HDQ16, ESCL, ESDA		-0.3		0.8	V
V_{IHS}	Input voltage high SMBC, SMBD, HDQ16, ESCL, ESDA		1.7		6.0	V
V_{AI}	Input voltage range VCELL1–4, TS, SRC		$V_{SS} - 0.3$		1.25	V
I_{RB}	RBI data-retention input current	$V_{RBI} > 3\text{ V}$, $V_{CC} < 2\text{ V}$		10	50	nA
V_{RBI}	RBI data-retention voltage		1.3			V
Z_{AI1}	Input impedance: SR1, SR2	0–1.25 V	10			M Ω
Z_{AI2}	Input impedance: VCELL1–4, TS, SRC	0–1.25 V	5			M Ω

VFC CHARACTERISTICS

 $V_{CC} = 3.1\text{ to }3.5\text{ V}$, $T_{OPR} = -0^{\circ}\text{C to }70^{\circ}\text{C}$, unless otherwise noted

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{SR}	Input voltage range, V_{SR2} and V_{SR1}	$V_{SR} = V_{SR2} - V_{SR1}$	-0.25		+0.25	V
V_{SROS}	V_{SR} input offset	$V_{SR2} = V_{SR1}$, autocorrection disabled	-250	-50	250	μV
V_{SRCOS}	Calibrated offset		-16		+16	μV
RM_{VCO}	Supply voltage gain coefficient ⁽¹⁾	$V_{CC} = 3.3\text{ V}$		0.8	1.2	%/V
RM_{TCO}	Temperature gain coefficient ⁽¹⁾	Slope for $T_{OPR} = -20^{\circ}\text{C to }70^{\circ}\text{C}$	-0.09		+0.09	%/°C
		Total deviation $T_{OPR} = -20^{\circ}\text{C to }70^{\circ}\text{C}$	-1.6%		0.1%	
		Slope for $T_{OPR} = -0^{\circ}\text{C to }50^{\circ}\text{C}$	-0.05		+0.05	%/°C
		Total deviation $T_{OPR} = -0^{\circ}\text{C to }50^{\circ}\text{C}$	-0.6%		0.1%	
INL	Integral nonlinearity error	$T_{OPR} = 0^{\circ}\text{C} - 50^{\circ}\text{C}$			0.21%	

(1) $RM_{(TCO)}$ total deviation is from the nominal gain at 25°C .

REG CHARACTERISTICS $T_{OPR} = -20^{\circ}\text{C}$ to 70°C

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{RO}	Normal mode: REG controlled output voltage	JFET: $R_{ds(on)} < 150\ \Omega$, $V_{gs(off)} < -3\ \text{V}$ at $10\ \mu\text{A}$	3.1	3.3	3.5	V
	Sleep mode: REG controlled output voltage				4	
I_{REG}	REG output current		1			μA

SMBus AC SPECIFICATIONS

 $V_{CC} = 2.7\text{ V to }3.7\text{ V}$, $T_{OPR} = -20^{\circ}\text{C to }70^{\circ}\text{C}$, unless otherwise noted

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f_{SMB}	SMBus operating frequency	Slave mode, SMBC 50% duty cycle	10		100	kHz
f_{MAS}	SMBus master clock frequency	Master mode, no clock low slave extend		51.2		kHz
t_{BUF}	Bus free time between start and stop		4.7			μs
$t_{HD:STA}$	Hold time after (repeated) start		4			μs
$t_{SU:STA}$	Repeated start setup time		4.7			μs
$t_{SU:STO}$	Stop setup time		4			μs
$t_{HD:DAT}$	Data hold time	Receive mode	0			ns
		Transmit mode	300			ns
$t_{SU:DAT}$	Data setup time		250			ns
$t_{TIMEOUT}$	Error signal/detect	See ⁽¹⁾	25		35	ms
t_{LOW}	Clock low period		4.7			μs
t_{HIGH}	Clock high period	See ⁽²⁾	4		50	μs
$t_{LOW:SEXT}$	Cumulative clock low slave extend time	See ⁽³⁾			25	ms
$t_{LOW:MEXT}$	Cumulative clock low master extend time	See ⁽⁴⁾			10	ms

(1) The bq2060A times out when any clock low exceeds TTIMEOUT.

(2) THIGH Max. is minimum bus idle time. SMBC = 1 for $t > 50\text{ ms}$ causes reset of any transaction involving bq2060A that is in progress.

(3) TLOW:SEXT is the cumulative time a slave device is allowed to extend the clock cycles in one message from initial start to the stop.

The bq2060A typically extends the clock only 20 ms as a slave in the read byte or write byte protocol.

(4) TLOW:MEXT is the cumulative time a master device is allowed to extend the clock cycles in one message from initial start to the stop.

The bq2060A typically extends the clock only 20 ms as a master in the read byte or write byte protocol.

HDQ16 AC SPECIFICATIONS

 $V_{CC} = 2.7\text{ V to }3.7\text{ V}$, $T_{OPR} = -20^{\circ}\text{C to }70^{\circ}\text{C}$, unless otherwise noted

SYMBOL	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{CYCH}	Cycle time, host to bq2060A (write)		190			μs
t_{CYCB}	Cycle time, bq2060A to host (read)		190	205	250	μs
t_{STRH}	Start hold time, host to bq2060A(write)		5	—	—	ns
t_{STRB}	Start hold time, bq2060A to host (read)		32	—	—	μs
DSU	Data setup time		—	—	50	μs
t_{DSUB}	Data setup time		—	—	50	μs
t_{DH}	Data hold time		100	—	—	μs
t_{DV}	Data valid time		80	—	—	μs
t_{SSU}	Stop setup time		—	—	145	μs
t_{SSUB}	Stop setup time		—	—	145	μs
t_{RSPS}	Response time, bq2060A to host		190	—	320	μs
t_j	Break time		190	—	—	μs
t_{BR}	Break recovery time		40	—	—	μs

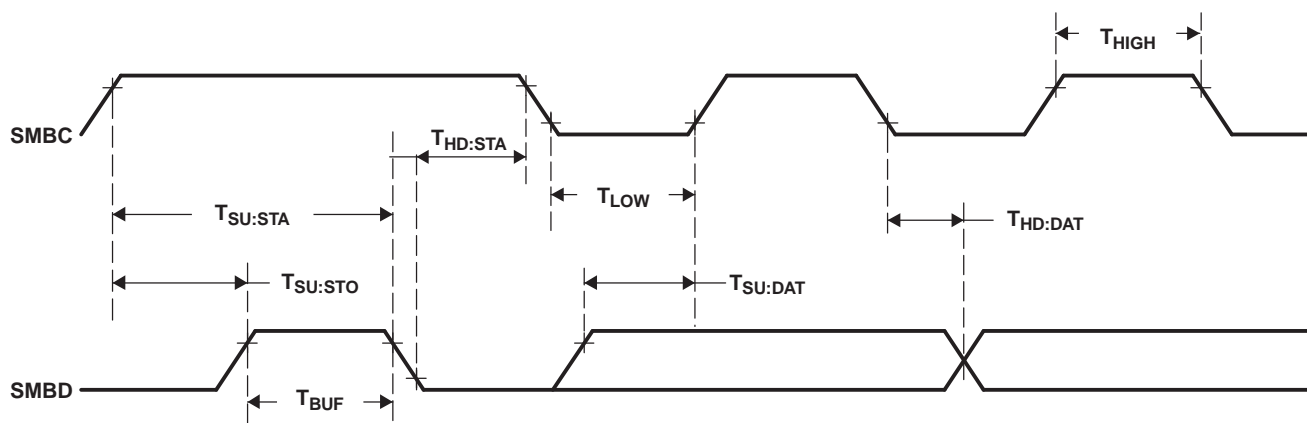


Figure 1. SMBus Timing Data

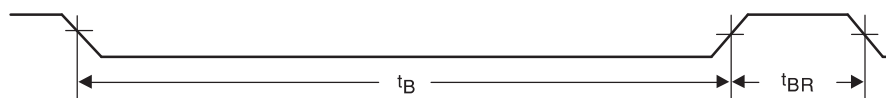


Figure 2. HDQ16 Break Timing

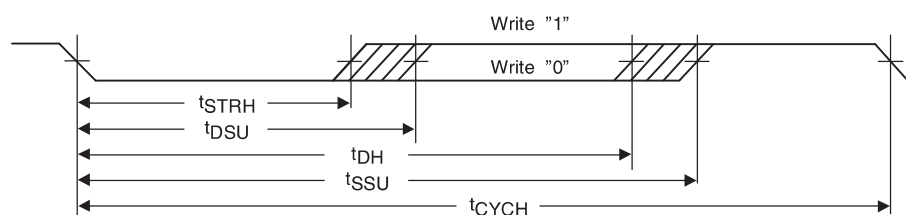


Figure 3. HDQ16 Host to bq2060A

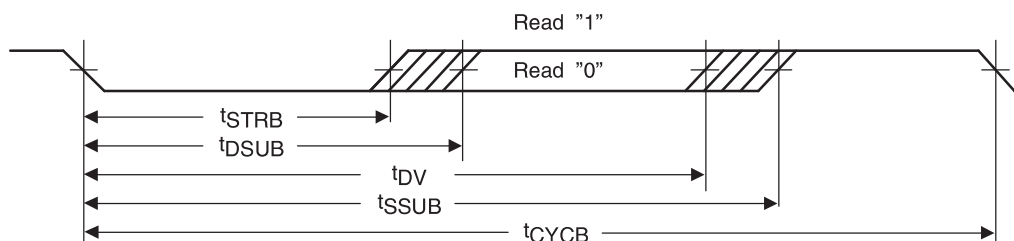


Figure 4. HDQ16 bq2060A to Host

FUNCTIONAL DESCRIPTION

General Operation

The bq2060A determines battery capacity by monitoring the amount of charge input or removed from a rechargeable battery. In addition to measuring charge and discharge, the bq2060A measures battery voltage, temperature, and current, estimates battery self-discharge, and monitors the battery for low-voltage thresholds. The bq2060A measures charge and discharge activity by monitoring the voltage across a small-value series sense resistor between the battery negative terminal and the negative terminal of the battery pack. The available battery charge is determined by monitoring this voltage and correcting the measurement for environmental and operating conditions.

Figure 5 shows a typical bq2060A-based battery-pack application. The circuit consists of the LED display, voltage and temperature measurement networks, EEPROM connections, a serial port, and the sense resistor. The EEPROM stores basic battery-pack configuration information and measurement-calibration values. The EEPROM must be programmed properly for bq2060A operation. **Table 9** shows the EEPROM memory map and outlines the programmable functions available in the bq2060A.

The bq2060A accepts an NTC thermistor (Semitec 103AT) for temperature measurement. The bq2060A uses the thermistor temperature to monitor battery-pack temperature, detect a battery full-charge condition, and compensate for self-discharge and charge/discharge battery efficiencies.

Measurements

The bq2060A uses a fully differential, dynamically balanced voltage-to-frequency converter (VFC) for charge measurement and a sigma delta analog-to-digital converter (ADC) for battery voltage, current, and temperature measurement.

Voltage, current, and temperature measurements are made every 2–2.5 seconds, depending on the bq2060A operating mode. Maximum times occur with compensated EDV, mWh mode, and maximum allowable discharge rate. Any AtRate computations requested or scheduled (every 20 seconds) may add up to 0.5 second to the time interval.

Charge and Discharge Counting

The VFC measures the charge and discharge flow of the battery by monitoring a small-value sense resistor between the SR₁ and SR₂ pins as shown in **Figure 5**. The VFC measures bipolar signals up to 250 mV. The bq2060A detects charge activity when $V_{SR} = V_{SR2} - V_{SR1}$ is positive and discharge activity when $V_{SR} = V_{SR2} - V_{SR1}$ is negative. The bq2060A continuously integrates the signal over time using an internal counter. The fundamental rate of the counter is 6.25 µVh.

Offset Calibration

The bq2060A provides an auto-calibration feature to cancel the voltage offset error across SR₁ and SR₂ for maximum charge measurement accuracy. The calibration routine is initiated by issuing a command to Manufacturer Access(). The bq2060A is capable of automatic offset calibration down to 6.25 µV. Offset cancellation resolution is less than 1 µV.

Digital Filter

The bq2060A does not measure charge or discharge counts below the digital filter threshold. The digital filter threshold is programmed in the EEPROM and should be set sufficiently high to prevent false signal detection with no charge or discharge flowing through the sense resistor.

Voltage

While monitoring SR₁ and SR₂ for charge and discharge currents, the bq2060A monitors the battery-pack potential and the individual cell voltages through the VCELL₁ – VCELL₄ pins. The bq2060A measures the pack voltage and reports the result in Voltage(). The bq2060A can also measure the voltage of up to four series elements in a battery pack. The individual cell voltages are stored in the optional Manufacturer Function area.

The VCELL₁ – VCELL₄ inputs are divided down from the cells using precision resistors, as shown in **Figure 5**. The maximum input for VCELL₁ – VCELL₄ is 1.25 V with respect to V_{SS}. The voltage dividers for the inputs must be set so that the voltages at the inputs do not exceed the 1.25-V limit under all operating conditions. Also, the divider ratios on VCELL₁ – VCELL₂ must be half of that of VCELL₃ – VCELL₄. To reduce current consumption from the battery, the CVON output may be used to connect the divider to the cells only during measurement period. CVON is high impedance for 250 ms (12.5% duty cycle) when the cells are measured, and driven low otherwise (see **Table 1**).

The SRC input of the bq2060A measures battery charge and discharge current. The SRC ADC input converts the current signal from the series sense resistor and stores the result in Current(). The full-scale input range to SBC is limited to ±250 mV as shown in **Table 2**.

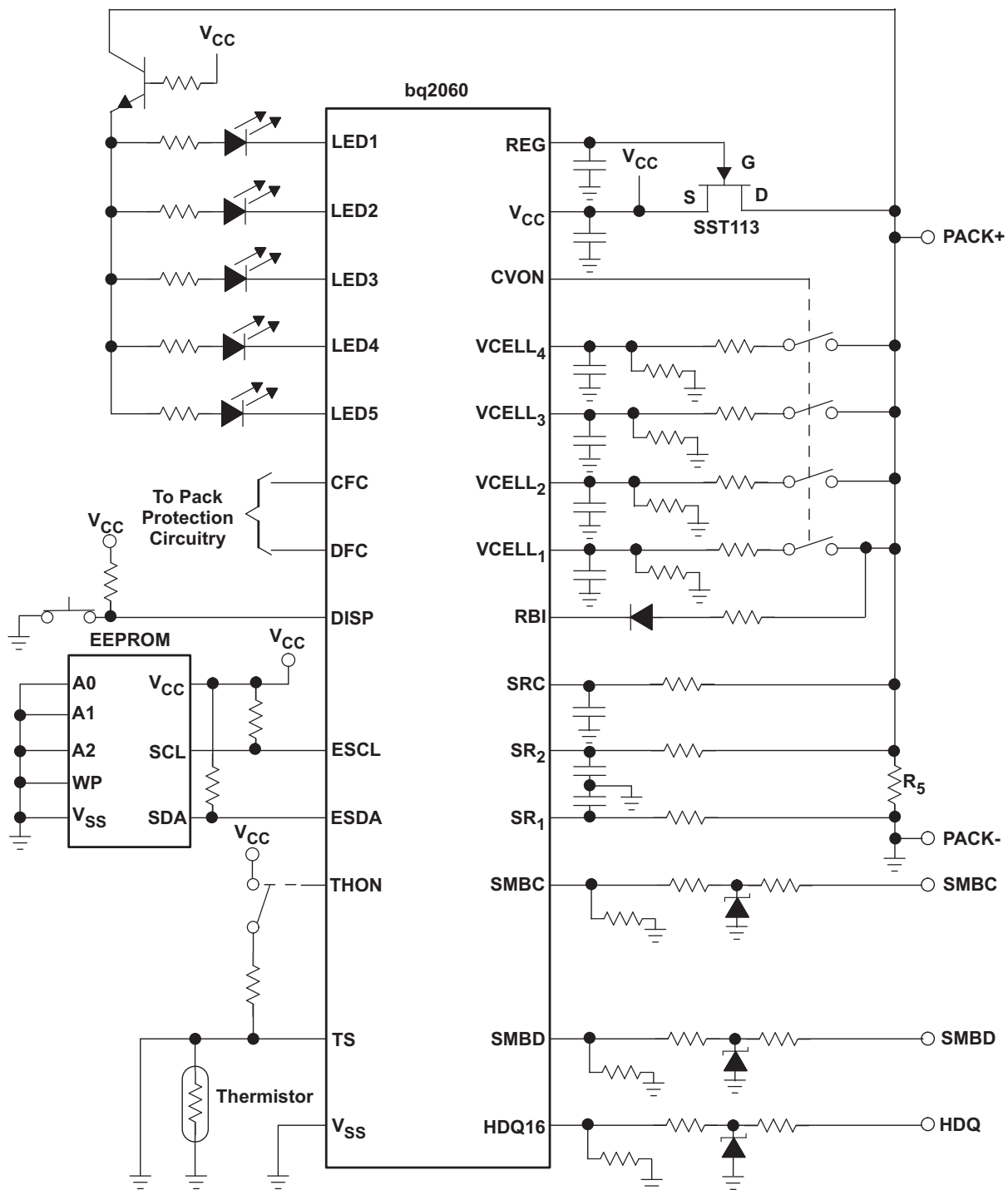


Figure 5. Battery Pack Application Diagram – LED Display and Series Cell Monitoring

Table 1. Example VCELL₁–VCELL₄ Divider and Input Range

VOLTAGE INPUT	VOLTAGE DIVISION RATIO	FULL-SCALE INPUT (V)
VCELL ₄	16	20
VCELL ₃	16	20
VCELL ₂	8	10
VCELL ₁	8	10

Table 2. SRC Input Range

SENSE RESISTOR (Ω)	FULL-SCALE INPUT (A)
0.02	± 12.5
0.03	± 8.3
0.05	± 5
0.1	± 2.5

Current

The SRC input of the bq2060A measures battery charge and discharge current. The SRC ADC input converts the current signal from the series sense resistor and stores the result in Current(). The full-scale input range to SBC is limited to ±250 mV, as shown in [Table 2](#).

Temperature

The TS input of the bq2060A along with an NTC thermistor measures the battery temperature as shown in [Figure 5](#). The bq2060A reports temperature in Temperature(). THON may be used to connect the bias source to the thermistor when the bq2060A samples the TS input. THON is high impedance for 60 ms when the temperature is measured, and driven low otherwise.

GAS GAUGE OPERATION

General

The operational overview in [Figure 6](#) illustrates the gas gauge operation of the bq2060A. [Table 3](#) and subsequent text describes the bq2060A registers.

The bq2060A accumulates a measure of charge and discharge currents and estimates self-discharge of the battery. The bq2060A compensates the charge current measurement for temperature and state-of-charge of the battery. It also adjusts the self-discharge estimation based on temperature.

The main counter RemainingCapacity()(RM) represents the available capacity or energy in the battery at any given time. The bq2060A adjusts RM for charge, self-discharge, and leakage compensation factors. The information in the RM register is accessible through the communications ports and is also represented through the LED display.

The FullChargeCapacity()(FCC) register represents the last measured full discharge of the battery. It is used as the battery full-charge reference for relative capacity indication. The bq2060A updates FCC when the battery undergoes a qualified discharge from nearly full to a low battery level. FCC is accessible through the serial communications ports.

The Discharge Count Register (DCR) is a non-accessible register that only tracks discharge of the battery. The bq2060A uses the DCR register to update the FCC register if the battery undergoes a qualified discharge from nearly full to a low battery level. In this way, the bq2060A learns the true discharge capacity of the battery under system use conditions.

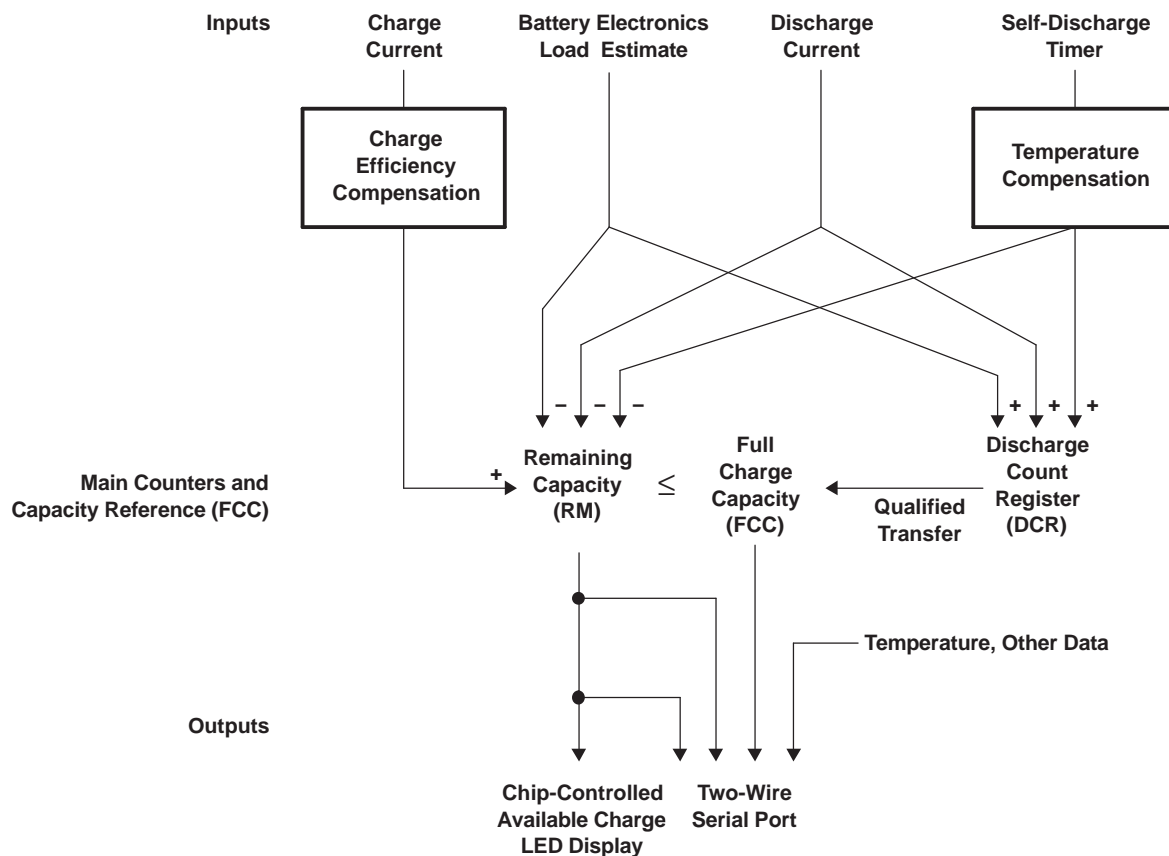


Figure 6. bq2060A Operational Overview

Table 3. bq2060A Register Functions

FUNCTION	COMMAND CODE		SMBus ACCESS	UNITS
	SMBus	HDQ16		
ManufacturerAccess	0x00	0x00	read/write	n/a
RemainingCapacityAlarm	0x01	0x01	read/write	mAh, 10mWh
RemainingTimeAlarm	0x02	0x02	read/write	minutes
BatteryMode	0x03	0x03	read/write	n/a
AtRate	0x04	0x04	read/write	mA, 10mW
AtRateTimeToFull	0x05	0x05	read	minutes
AtRateTimeToEmpty	0x06	0x06	read	minutes
AtRateOK	0x07	0x07	read	Boolean
Temperature	0x08	0x08	read	0.1 K
Voltage	0x09	0x09	read	mV
Current	0x0a	0x0a	read	mA
AverageCurrent	0x0b	0x0b	read	mA
MaxError	0x0c	0x0c	read	percent
RelativeStateOfCharge	0x0d	0x0d	read	percent
AbsoluteStateOfCharge	0x0e	0x0e	read	percent
RemainingCapacity	0x0f	0x0f	read	mAh, 10mWh
FullChargeCapacity	0x10	0x10	read	mAh, 10mWh
RunTimeToEmpty	0x11	0x11	read	minutes

Table 3. bq2060A Register Functions (continued)

FUNCTION	COMMAND CODE		SMBus ACCESS	UNITS
	SMBus	HDQ16		
AverageTimeToEmpty	0x12	0x12	read	minutes
AverageTimeToFull	0x13	0x13	read	minutes
ChargingCurrent	0x14	0x14	read	mA
ChargingVoltage	0x15	0x15	read	mV
Battery Status	0x16	0x16	read	n/a
CycleCount	0x17	0x17	read	cycles
DesignCapacity	0x18	0x18	read	mAh, 10mWh
DesignVoltage	0x19	0x19	read	mV
SpecificationInfo	0x1a	0x1a	read	n/a
ManufactureDate	0x1b	0x1b	read	n/a
SerialNumber	0x1c	0x1c	read	integer
Reserved	0x1d–0x1f	0x1d – 0x1f	–	–
ManufacturerName	0x20	0x20–0x25	read	string
DeviceName	0x21	0x28–0x2b	read	string
DeviceChemistry	0x22	0x30–0x32	read	string
ManufacturerData	0x23	0x38–0x3b	read	string
Pack Status	0x2f (LSB)	0x2f (LSB)	read/write	n/a
Pack Configuration	0x2f (MSB)	0x2f (MSB)	read/write	n/a
VCELL4	0x3c	0x3c	read/write	mV
VCELL3	0x3d	0x3d	read/write	mV
VCELL2	0x3e	0x3e	read/write	mV
VCELL1	0x3f	0x3f	read/write	mV

MAIN GAS GAUGE REGISTERS

RemainingCapacity() (RM)

RM represents the remaining capacity in the battery. The bq2060A computes RM in either mAh or 10mWh, depending on the selected mode.

On initialization, the bq2060A sets RM to 0. RM counts up during charge to a maximum value of FCC and down during discharge and self-discharge to 0. In addition to charge and self-discharge compensation, the bq2060A calibrates RM at three low-battery-voltage thresholds, EDV2, EDV1, and EDV0 and three programmable midrange thresholds VOC25, VOC50, and VOC75. This provides a voltage-based calibration to the RM counter.

DesignCapacity() (DC)

The DC is the user-specified battery full capacity. It is calculated from *Pack Capacity* EE 0x3a–0x3b and is represented in mAh or 10mWh. It also represents the full-battery reference for the absolute display mode.

FullChargeCapacity() (FCC)

FCC is the last measured discharge capacity of the battery. It is represented in either mAh or 10mWh depending on the selected mode. On initialization, the bq2060A sets FCC to the value stored in *Last Measured Discharge* EE 0x38–0x39. During subsequent discharges, the bq2060A updates FCC with the last measured discharge capacity of the battery. The last measured discharge of the battery is based on the value in the DCR register after a qualified discharge occurs. Once updated, the bq2060A writes the new FCC value to EEPROM in mAh to *Last Measured Discharge*. FCC represents the full battery reference for the relative display mode and relative state of charge calculations.

Discharge Count Register (DCR)

The DCR register counts up during discharge, independent of RM. DCR can continue to count even after RM has counted down to 0. Prior to RM = 0, discharge activity, light discharge estimation and self-discharge increment DCR. After RM = 0, only discharge activity increments DCR. The bq2060A initializes DCR to FCC – RM when FCC-RM is less than twice the programmed value in *Near Full* EE 0x55. The DCR initial value of FCC – RM is reduced by FCC/128 if SC = 0 (bit 2 in Control Mode) and is not reduced if SC = 1. DCR stops counting when the battery voltage reaches the EDV2 threshold on discharge.

Capacity Learning (FCC Update) and Qualified Discharge

The bq2060A updates FCC with an amount based on the value in DCR if a qualified discharge occurs. The new value for FCC equals the DCR value plus the programmable nearly full and low battery levels, according to the following equation:

$$\text{FCC}(\text{new}) = \text{DCR}(\text{final}) = \text{DCR}(\text{initial}) + \text{measured discharge to EDV2} + (\text{FCC} \times \text{BatteryLow}\%) \quad (1)$$

Where:

$$\text{BatteryLow}\% = (\text{value stored in EE 0x54}) + 2.56$$

A qualified discharge occurs if the battery discharges from $\text{RM} \geq \text{FCC} - \text{Near Full} \times 2$ to the EDV2 voltage threshold with the following conditions:

- No valid charge activity occurs during the discharge period. A valid charge is defined as an input of 10 mAh into the battery.
- No more than 256 mAh of self-discharge and/or light discharge estimation occurs during the discharge period.
- The temperature does not drop below 5°C during the discharge period.
- The battery voltage reaches the EDV2 threshold during the discharge period and the voltage was between the EDV2 threshold and [EDV2 threshold – 256 mV] when the bq2060A detected EDV2.
- No midrange voltage correction occurs during the discharge period.
- No overload condition occurs when voltage \leq EDV2 threshold

FCC cannot be reduced by more than 256 mAh or increased by more than 512 mAh during any single update cycle. FCC becomes invalid if it is initialized or updated to a value less than 256 mAh. FCC becomes invalid if it is initialized or updated to a value less than 256 mAh. The bq2060A saves the new FCC value to the EEPROM within 4 s of being updated.

End-of-Discharge Thresholds and Capacity Correction

The bq2060A monitors the battery for three low-voltage thresholds, EDV0, EDV1, and EDV2. The EDV thresholds are programmed in *EDVF/EDV0* EE 0x72–0x73, *EMF/EDV1* EE 0x74–0x75, and *EDV C1/C0 Factor/EDV2* EE 0x78–0x79. If the CEDV bit in *Pack Configuration* is set, automatic EDV compensation is enabled, and the bq2060A computes the EDV0, EDV1, and EDV2 thresholds based on the values in EE 0x72–0x7d, 0x06, and the battery load current, temperature, capacity, and cycle count. The bq2060A disables EDV detection if Current() exceeds the *Overload Current* threshold programmed in EE 0x46–EE 0x47. The bq2060A resumes EDV threshold detection after the Current() drops below the overload current threshold. Any EDV threshold detected is reset after 10 mAh of charge is applied.

The bq2060A uses the thresholds to apply voltage-based corrections to the RM register according to [Table 4](#).

Table 4. State of Charge Based on Low Battery Voltage

THRESHOLD	STATE OF CHARGE IN RM
EDV0	0%
EDV1	3%
EDV2	Battery Low %

The bq2060A adjusts RM as it detects each threshold. If the voltage threshold is reached before the corresponding capacity on discharge, the bq2060A reduces RM to the appropriate amount as shown in [Table 4](#). If RM reaches the capacity level before the voltage threshold is reached on discharge, the bq2060A prevents RM from decreasing until the battery voltage reaches the corresponding threshold, but only on a full learning-cycle discharge (VDQ = 1). The EDV1 threshold is ignored if *Miscellaneous Options* bit 7 = 1.

Self-Discharge

The bq2060A estimates the self-discharge of the battery to maintain an accurate measure of the battery capacity during periods of inactivity. The algorithm for self-discharge estimation takes a programmed estimate for the expected self-discharge rate at 25°C stored in EEPROM and makes a fixed reduction to RM of an amount equal to RemainingCapacity()/256. The bq2060A makes the fixed reduction at a varying time interval that is adjusted to achieve the desired self-discharge rate. This method maintains a constant granularity of 0.39% for each self-discharge adjustment, which may be performed multiple times per day, instead of once per day with a potentially large reduction.

The self-discharge estimation rate for 25°C is doubled for each 10 degrees above 25°C or halved for each 10 degrees below 25°C. The following table shows the relation of the self-discharge estimation at a given temperature to the rate programmed for 25°C (Y% per day):

TEMPERATURE(C)	SELF-DISCHARGE RATE
Temp < 10	1/4Y% per day
10 ≤ Temp < 20	1/2 Y% per day
20 ≤ Temp < 30	Y% per day
30 ≤ Temp < 40	2Y% per day
40 ≤ Temp < 50	4Y% per day
50 ≤ Temp < 60	8Y% per day
60 ≤ Temp < 70	16Y% per day
70 ≤ Temp	32Y% per day

The interval at which RM is reduced is given by the following equation, where n is the appropriate factor of 2 (n = 1/ 4, 1/ 2, 1, 2 . . .):

$$\text{Self-DischargeUpdateTime} = \frac{640 \times 13500}{256 \times n \times (Y\% \text{ per day})} \text{ seconds} \quad (2)$$

The timer that keeps track of the self-discharge update time is halted whenever charge activity is detected. The timer is reset to zero if the bq2060A reaches the RemainingCapacity()=FullChargeCapacity() condition while charging.

Example: If T = 35°C (n = 2) and programmed self-discharge rate Y is 2.5 (2.5% per day at 25°C), the bq2060A reduces RM by RM/256 (0.39%) every

$$\frac{640 \times 135000}{256 \times n \times (Y\% \text{ per day})} = 6750 \text{ seconds} \quad (3)$$

This means that a 0.39% reduction of RM is made 12.8 times per day to achieve the desired 5% per day reduction at 35°C.

Figure 7 illustrates how the self-discharge estimate algorithm adjusts RemainingCapacity() vs. temperature.

Light Discharge or Suspend Current Compensation

The bq2060A can be configured in two ways to compensate for small discharge currents that produce a signal below the digital filter. First, the bq2060A can decrement RM and DCR at a rate determined by the value stored in *Light Discharge Current* EE 0x2b when it detects no discharge activity and the SMBC and SMBD lines are high. *Light Discharge Current* has a range of 44 µA to 11.2 mA.

Alternatively, the bq2060A can be configured to disable the digital filter for discharge when the SMBC and SMBD lines are high. In this way, the digital filter does not mask the leakage current signal. The bq2060A is configured in this mode by setting the NDF bit in *Control Mode*.

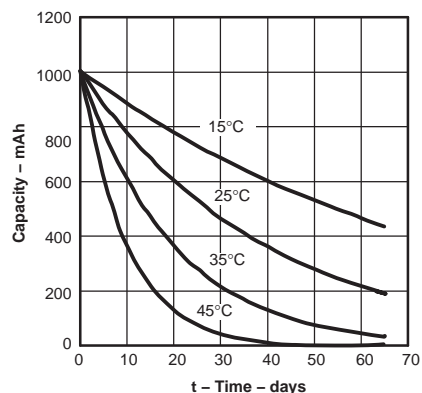


Figure 7. Self-Discharge at 2.5%/Day at 25°C

Midrange Capacity Corrections

The bq2060A applies midrange capacity corrections when the VCOR bit is set in *Pack Configuration*. The bq2060A adjusts RM to the associated percentage at three different voltage levels VOC25, VOC50, and VOC75. The VOC values represent the open-circuit battery voltage at which RM corresponds to the associated state of charge for each threshold.

THRESHOLD	ASSOCIATED STATE OF CHARGE
VOC25	25%
VOC50	50%
VOC75	75%

For the midrange corrections to occur, the temperature must be in the range of 19°C to 31°C inclusive and the Current() and AverageCurrent() must both be between –64 mA and 0. For a correction to occur, the bq2060A must also detect the need for correction during two adjacent measurements separated by 20 s. The second measurement is not required if the first measurement occurs immediately after a device reset. The bq2060A makes midrange corrections as shown in [Table 5](#).

Charge Control

Charging Voltage and Current Broadcasts

The bq2060A supports SBS charge control by broadcasting the ChargingCurrent() and ChargingVoltage() to the Smart Charger address. The bq2060A broadcasts the requests every 10 s. The bq2060A updates the values used in the charging current and voltage broadcasts based on the battery state of charge, voltage, and temperature. The fast-charge rate is programmed in *Fast-Charging Current* EE 0x1a–0x1b while the charge voltage is programmed in *Charging Voltage* EE 0x0a–0x0b.

The bq2060A internal charge control is compatible with popular rechargeable chemistries. The primary charge-termination techniques include a change in temperature over a change in time ($\Delta T/\Delta t$) and current taper, for nickel-based and Li-ion chemistries, respectively. The bq2060A also provides pre-charge qualification and a number of safety charge suspensions based on current, voltage, temperature, and state of charge.

Alarm Broadcasts to Smart Charger and Host

If any of the bits 8–15 in BatteryStatus() is set, the bq2060A broadcasts an AlarmWarning() message to the host address. If any of the bits 12–15 in BatteryStatus() is set, the bq2060A also sends an AlarmWarning() message to the Smart Charger address. The bq2060A repeats the AlarmWarning() message every 10 s until the bits are cleared.

Pre-Charge Qualification

The bq2060A sets ChargingCurrent() to the pre-charge rate as programmed in *Pre-Charge Current* EE 0x1e–0x1f under the following conditions:

- **Voltage:** The bq2060A requests the pre-charge charge rate when Voltage() drops below the EDV0 threshold (compensated or fixed EDVs). Once requested, a pre-charge rate remains until Voltage() increases above the EDVF threshold. The bq2060A also broadcasts the pre-charge value immediately after a device reset until Voltage() is above the EDVF threshold. This threshold is programmed in *EDVF/EDV0* EE 0x72–0x73.
- **Temperature:** The bq2060A requests the pre-charge rate when Temperature() is between 0°C and 5°C. Temperature() must rise above 5°C before the bq2060A requests the fast-charge rate.

Charge Suspension

The bq2060A may temporarily suspend charge if it detects a charging fault. A charging fault includes the following conditions.

- **Overcurrent:** An overcurrent condition exists when the bq2060A measures the charge current to be more than the *Overcurrent Margin* above the ChargingCurrent(). *Overcurrent Margin* is programmed in EE 0x49. On detecting an overcurrent condition, the bq2060A sets the ChargingCurrent() to zero and sets the TERMINATE_CHARGE_ALARM bit in BatteryStatus(). The overcurrent condition and TERMINATE_CHARGE_ALARM are cleared when the measured current drops below the ChargingCurrent plus the *Overcurrent Margin*.
- **Overvoltage:** An overvoltage condition exists when the bq2060A measures the battery voltage to be more than the *Overvoltage Margin* above the ChargingVoltage() or a Li-ion cell voltage has exceeded the overvoltage limit programmed in *Cell Under-/Overvoltage*. *Overvoltage Margin* is programmed in EE 0x48 and *Cell Under-/Overvoltage* in EE 0x4a. On detecting an overvoltage condition, the bq2060A sets the ChargingCurrent() to zero and sets the TERMINATE_CHARGE_ALARM bit in BatteryStatus(). The bq2060A clears the TERMINATE_CHARGE_ALARM bit when it detects that the battery is no longer being charged (DISCHARGING bit set in BatteryStatus()). The bq2060A continues to broadcast zero charging current until the overvoltage condition is cleared. The overvoltage condition is cleared when the measured battery voltage drops below the ChargingVoltage() plus the *Overvoltage Margin* or when the CVOV bit is reset.
- **Overtemperature:** An overtemperature condition exists when Temperature() is greater than or equal to the *MaxT* value programmed in EE 0x45 (most significant nibble). On detecting an overtemperature condition, the bq2060A sets the ChargingCurrent() to zero and sets the OVER_TEMP_ALARM and TERMINATE_CHARGE_ALARM bit in BatteryStatus() and the CVOV bit in Pack Status. The overtemperature condition is cleared when Temperature() is equal to or below (*MaxT* – 5°C). The temperature set by *MaxT* is increased by 16°C if bit 5 in *Miscellaneous Options* is set.
- **Overcharge:** An overcharge condition exists if the battery is charged more than the *Maximum Overcharge* value after RM = FCC. *Maximum Overcharge* is programmed in EE 0x2e–0x2f. On detecting an overcharge condition, the bq2060A sets the ChargingCurrent() to zero and sets the OVER_CHARGED_ALARM, TERMINATE_CHARGE_ALARM, and FULLY_CHARGED bits in BatteryStatus(). The bq2060A clears the OVER_CHARGED_ALARM and TERMINATE_CHARGE_ALARM when it detects that the battery is no longer being charged. The FULLY_CHARGED bit remains set and the bq2060A continues to broadcast zero charging current until RelativeStateOfCharge() is less than *Fully Charged Clear%* programmed in EE 0x4c. The counter used to track overcharge capacity is reset with 2 mAh of discharge.
- **Undertemperature:** An undertemperature condition exists if Temperature() < 0°C. On detecting an under temperature condition, the bq2060A sets ChargingCurrent() to zero. The bq2060A sets ChargingCurrent() to the appropriate pre-charge rate or fast-charge rate when Temperature() ≥ 0°C.

Table 5. Midrange Corrections

CONDITION		RESULT
Voltage()	≥ VOC75 and RelativeStateOfCharge() ≤ 63%	RelativeStateOfCharge()→75%
	< VOC75 and RelativeStateOfCharge() ≥ 87%	RelativeStateOfCharge()→75%
	≥VOC50 and RelativeStateOfCharge() ≤ 38%	RelativeStateOfCharge()→50%
	<VOC50 and RelativeStateOfCharge() ≥ 62%	RelativeStateOfCharge()→50%
	≥ VOC25 and RelativeStateOfCharge() ≤ 13%	RelativeStateOfCharge()→25%
	< VOC25 and RelativeStateOfCharge() ≥ 37%	RelativeStateOfCharge()→25%

Primary Charge Termination

The bq2060A terminates charge if it detects a charge-termination condition. A charge-termination condition includes the following.

- **$\Delta T/\Delta t$:** For $\Delta T/\Delta t$, the bq2060A detects a change in temperature over many seconds. The $\Delta T/\Delta t$ setting is programmable in both the temperature step, *DeltaT* (1.6°C – 4.6°C), and the time step, *DeltaT Time* (20 s – 320 s). Typical settings for 1°C/minute include 2°C/120 s and 3°C/180 s. Longer times are required for increased slope resolution. The *DeltaT* value is programmed in EE 0x45 (least significant nibble) and the *Delta T Time* in EE 0x4e.
In addition to the $\Delta T/\Delta t$ timer, a holdoff timer starts when the battery is being charged at more than 255 mA and the temperature is above 25°C. Until this timer expires, $\Delta T/\Delta t$ detection is suspended. If Current() drops below 256 mA or Temperature() below 25°C, the holdoff timer resets and restarts only when the current and temperature conditions are met again. The holdoff timer is programmable (20 s – 320 s) with Holdoff Time value in EE 0x4f.
- **Current Taper:** For current taper, ChargingVoltage() must be set to the pack voltage desired during the constant-voltage phase of charging. The bq2060A detects a current taper termination when the pack voltage is greater than the voltage determined by *Current Taper Qual Voltage* in EE 0x4f and the charging current is below a threshold determined by *Current Taper Threshold* in EE 0x4e, for at least 80 s. The bq2060A uses the VFC to measure current for current taper termination. The current must also remain above 0.5625/R_S mA to qualify the termination condition.

Once the bq2060A detects a primary charge termination, it sets the TERMINATE_CHARGE_ALARM and FULLY_CHARGED bits in BatteryStatus(), and sets the ChargingCurrent() to the maintenance charge rate as programmed in *Maintenance Charging Current* EE 0x1c–0x1d. On termination, the bq2060A also sets RM to a programmed percentage of FCC, provided that RelativeStateOfCharge() is below the desired percentage of FCC and the CSYNC bit in *Pack Configuration* EE 0x3f is set. The programmed percentage of FCC, *Fast Charge Termination %*, is set in EE 0x4b. The bq2060A clears the FULLY_CHARGED bit when RelativeStateOfCharge() is less than the programmed *Fully Charged Clear %*. The bq2060A broadcasts the fast-charge rate when the FULLY_CHARGED bit is cleared and voltage and temperature permit. The bq2060A clears the TERMINATE_CHARGE_ALARM when it no longer detects that the battery is being charged or it no longer detects the termination condition. See [Table 6](#) for a summary of BatteryStatus() alarm and status bit operation.

Display Port

General

The display port drives a 4- or 5-LED bar-graph display. The display is activated by a logic signal on the $\overline{\text{DISP}}$ input. The bq2060A can display RM in either a relative or absolute mode with each LED representing a percentage of the full-battery reference. In relative mode, the bq2060A uses FCC as the full-battery reference; in absolute mode, it uses DC.

The DMODE bit in *Pack Configuration* programs the bq2060A for the absolute or relative display mode. The LED bit in Control Mode programs the 4- or 5-LED option. A 5th LED can be used with the 4-LED display option to show when the battery capacity is \geq to 100%.

Activation

The display may be activated at any time by a high-to-low transition on the $\overline{\text{DISP}}$ input. This is usually accomplished with a pullup resistor and a pushbutton switch. Detection of the transition activates the display and starts a 4-s display timer. The timer expires and turns off the display whether $\overline{\text{DISP}}$ was brought low momentarily or held low indefinitely. Reactivation of the display requires that the $\overline{\text{DISP}}$ input return to a logic-high state and then transition low again. The second high-to-low transition must occur after the display timer expires. The bq2060A requires the DISP input to remain stable for a minimum of 250 ms to detect the logic state.

If the EDV0 bit is set, the bq2060A disables the LED display. The display is also disabled during a VFC calibration and should be turned off before entering low-power storage mode.

Display Modes

In relative mode, each LED output represents 20% or 25% of the RelativeStateOfCharge() value. In absolute mode, each LED output represents 20% or 25% of the AbsoluteStateOfCharge() value. [Table 7](#) and [Table 8](#) show the display operation.

In either mode, the bq2060A blinks the LED display if RemainingCapacity() is less than RemainingCapacityAlarm(). The display is disabled if EDV0 = 1.

Secondary Protection for Li-ion

The bq2060A has two pins, CFC and DFC, that can be used for secondary override control of a Li-ion protector or for blowing a fuse to disable the battery pack. The CFC pin is the Charge FET Control pin for secondary protector control or for blowing a fuse. The DFC pin is the Discharge FET Control pin for secondary protector control. Discharge current can cause an override of the CFC control, and charge current can cause an override of the DFC control. The CVOV, CVUV, and the true logic state of the CFC and DFC pins can be read in the lower nibble of Pack Status.

The CVOV status flag is set if Voltage() \geq ChargingVoltage() + *Overvoltage Margin*, any VCELL voltage \geq Cell Overvoltage threshold, or if Temperature() \geq MaxT. When CVOV = 1 and Miscellaneous Options bit 6 = 0, the CFC pin is pulled low unless the DISCHARGING bit in BatteryStatus() is set. If Temperature > Safety Overtemperature threshold, then it is pulled low even if the Discharging bit in BatteryStatus() is set.

The formula for this description is:

$$\overline{\text{CFC}} = \text{SOT}$$

or

$$\text{CVOV} + \overline{\text{DSG}} + \overline{\text{MISC OPTION BIT 6}}$$

If Miscellaneous Options bit 6 = 1, the CFC pin is pulled low only if Temperature() > Safety Overtemperature threshold.

Table 6. Alarm and Status Bit Summary⁽¹⁾

BATTERY STATE	CONDITIONS	CC() STATE AND BatteryStatus BIT SET	CC() = FAST OR PRECHARGE CURRENT AND/OR BITS CLEARED
Overcurrent	$C() \geq CC() + \text{Overcurrent Margin}$	$CC() = 0, TCA = 1$	$C() < CC() + \text{Overcurrent Margin}$
Overvoltage	$V() \geq CV() + \text{Overvoltage Margin}$ $VCELL1, 2, 3, \text{ or } 4 > \text{Cell Over Voltage}$	$TCA = 1$	$DISCHARGING = 1$
		$CC() = 0, CVOV = 1$	$V() < CV() + \text{Overvoltage Margin}$ Li-ion cell voltage \leq Cell Over Voltage
Over temperature	$T() \geq \text{MaxT}$	$CC() = 0, OTA = 1,$ $TCA = 1, CVOV = 1$	$T() \leq \text{MaxT} - 5^\circ\text{C}$ or $T() \leq 43^\circ\text{C}$
Overcharge	Capacity added after $RM() = FCC() \geq$ Maximum Overcharge	$CC() = 0, FC = 1$	$RSOC() < \text{Fully Charged Cleared \%}$
		$OCA = 1, TCA = 1$	$DISCHARGING = 1$
Undertemperature	$T() < 0^\circ\text{C}$	$CC() = 0$	$0^\circ\text{C} \leq T() < 5^\circ\text{C},$ $CC() = \text{Pre-Charge Current};$ $T() \geq 5^\circ\text{C},$ $CC() = \text{Fast-Charging Current}$
Fast-charge termination	$\Delta T/\Delta t$ or Current Taper	$CC() = \text{Maintenance Charging Current},$ $FC = 1$	$RSOC() < \text{Fully Charged Cleared \%}$
		$TCA = 1$	$DISCHARGING = 1$ or termination condition is no longer valid.
Fully discharged	$V() \leq \text{EDV2}$ or $RM() < FCC() * \text{Battery Low\%}$	$FD = 1$	$RSOC() > 20\%$
Overdischarged	$V() \leq \text{EDV0}$	$TDA = 1$	$V() > \text{EDV0}$
	$VCELL1, 2, 3 \text{ or } 4 < \text{Cell Under Voltage}$	$TDA = 1, CVUV = 1$	$VCELL1, 2, 3, \text{ or } 4 \geq \text{Cell Under Voltage}$
	$RM() = 0$	$TDA = 1$	$RM() > 0$
Low capacity	$RM() < \text{RCA}()$	$\text{RCA} = 1$	$RM() \geq \text{RCA}()$
Low run-time	$\text{ATTE}() < \text{RTA}()$	$\text{RTA} = 1$	$\text{ATTE}() \geq \text{RTA}()$

(1) C() = Current(), CV() = ChargingVoltage(), CC() = ChargingCurrent(), V() = Voltage(), T() = Temperature(), TCA = TERMINATE_CHARGE_ALARM, OTA = OVER_TEMPERATURE_ALARM, OCA = OVER_CHARGED_ALARM, TDA = TERMINATE_DISCHARGE_ALARM, FC = FULLY_CHARGED, FD = FULLY_DISCHARGED, RSOC() = RelativeStateOfCharge(). RM() = RemainingCapacity(), RCA = REMAINING_CAPACITY_ALARM, RTA = REMAINING_TIME_ALARM, ATTE() = AverageTimeToEmpty(), RTA() = RemainingTimeAlarm(), RCA() = RemainingCapacityAlarm(), FCC() = FullChargeCapacity().

Table 7. 5-LED Display Mode

Condition Relative or Absolute StateOfCharge()	5-LED Display Option				
	LED1	LED2	LED3	LED4	LED5
EDV0 = 1	OFF	OFF	OFF	OFF	OFF
<20%	ON	OFF	OFF	OFF	OFF
≤20%, <40%	ON	ON	OFF	OFF	OFF
≤40%, <60%	ON	ON	ON	OFF	OFF
≤60%, <80%	ON	ON	ON	ON	OFF
≤80%	ON	ON	ON	ON	ON

Table 8. 4-LED Display Mode

Condition Relative or Absolute StateOfCharge()	4-LED Display Option			
	LED1	LED2	LED3	LED4
EDV0 = 1	OFF	OFF	OFF	OFF
<25%	ON	OFF	OFF	OFF
≤25%, <50%	ON	ON	OFF	OFF
≤50%, <75%	ON	ON	ON	OFF
≤75%	ON	ON	ON	ON

The CVUV status flag is set if any VCELL voltage < *Cell Undervoltage* threshold. When CVUV = 1, the DFC pin is pulled low unless DISCHARGING bit in BatteryStatus() is clear (not set).

Cell Undervoltage and *Cell Overvoltage* limits may be programmed in the upper and lower nibbles of EE 0x4a. *Safety Overtemperature* threshold may be programmed in EE 0x09, and *Miscellaneous Options* is programmed in EE 0x08.

Low-Power Storage Mode

The bq2060A enters low-power mode 5 s to 8 s after receiving the Enable Low-Power command. In this mode, the bq2060A consumes less than 10 μ A. A rising edge on SMBC, SMBD, or HDQ16 restores the bq2060A to the full operating mode. The bq2060A does not perform any gas gauge functions during low-power storage mode.

Device Reset

The bq2060A can be reset when power is applied or by commands over the HDQ16 or SMBus. On reset, the bq2060A initializes its internal registers with the information contained in the configuration EEPROM. The following command sequence initiates a full bq2060A reset:

```
Write 0xff5a to address 0x4f
Write 0x0000 to address 0x7d
Write 0x0080 to address 0x7d
```

A partial reset of the bq2060A occurs if step 1 is omitted and all check-byte values previously loaded into RAM are still correct. All initial RAM values are read from EEPROM for both full and partial resets. A full reset initializes MaxError = 100%, sets RELEARN_FLAG (bit 7) = 1 in Battery Mode, and initializes RM from EE 0x2c–2d (should be zero for rechargeable batteries). A partial reset leaves MaxError, RELEARN_FLAG, and RM unchanged. The bq2060A delays reading the EEPROM for 700 ms after all resets to allow settling time for V_{CC} .

COMMUNICATION

The bq2060A includes two types of communication ports: SMBus and HDQ16. The SMBus interface is a 2-wire bidirectional protocol using the SMBC (clock) and SMBD (data) pins. The HDQ16 interface is a 1-wire bidirectional protocol using the HDQ16 pin. All three communication lines are isolated from V_{CC} and may be pulled up higher than V_{CC} . Also, the bq2060A does not pull these lines low if V_{CC} to the part is zero. HDQ16 should be pulled down with a 100-k Ω resistor if not used.

The communication ports allow a host controller, an SMBus compatible device, or other processor to access the memory registers of the bq2060A. In this way, a system can efficiently monitor and manage the battery.

SMBus

The SMBus interface is a command-based protocol. A processor acting as the bus master initiates communication to the bq2060A by generating a START condition. A START condition consists of a high-to-low transition of the SMBD line while the SMBC is high. The processor then sends the bq2060A device address of 0001011 (bits 7–1) plus a R/W bit (bit 0) followed by an SMBus command code. The R/W bit and the command code instruct the bq2060A to either store the forthcoming data to a register specified by the SMBus command code or output the data from the specified register. The processor completes the access with a STOP condition. A STOP condition consists of a low-to-high transition of the SMBD line while the SMBC is high. With SMBus, the most significant bit of a data byte is transmitted first.

In some instances, the bq2060A acts as the bus master. This occurs when the bq2060A broadcasts charging requirements and alarm conditions to device addresses 0x12 (SBS Smart Charger) and 0x10 (SBS Host Controller.)

SMBus Protocol

The bq2060A supports the following SMBus protocols:

- Read Word
- Write Word
- Read Block

A processor acting as the bus master uses the three protocols to communicate with the bq2060A. The bq2060A acting as the bus master uses the Write Word protocol.

The SMBD and SMBC pins are open drain and require external pullup resistors.

SMBus Packet Error Checking

The bq2060A supports Packet Error Checking as a mechanism to confirm proper communication between it and another SMBus device. Packet Error Checking requires that both the transmitter and receiver calculate a Packet Error Code (PEC) for each communication message. The device that supplies the last byte in the communication message appends the PEC to the message. The receiver compares the transmitted PEC to its PEC result to determine if there is a communication error.

PEC Protocol

The bq2060A can receive or transmit data with or without PEC. [Figure 9](#) shows the communication protocol for the Read Word, Write Word, and Read Block messages without PEC. [Figure 8](#) includes PEC.

In the Write Word protocol, the bq2060A receives the PEC after the last byte of data from the host. If the host does not support PEC, the last byte of data is followed by a STOP condition. After receipt of the PEC, the bq2060A compares the value to its calculation. If the PEC is correct, the bq2060A responds with an ACKNOWLEDGE. If it is not correct, the bq2060A responds with a NOT ACKNOWLEDGE and sets an error code.

In the Read Word and Block Read, the host generates an ACKNOWLEDGE after the last byte of data sent by the bq2060A. The bq2060A then sends the PEC and the host acting as a master receiver generates a NOT ACKNOWLEDGE and a STOP condition.

PEC Calculation

The basis of the PEC calculation is an 8-bit Cyclic Redundancy Check (CRC-8) based on the polynomial $C(X) = X^8 + X^2 + X^1 + 1$. The PEC calculation includes all bytes in the transmission, including address, command, and data. The PEC calculation does not include ACKNOWLEDGE, NOT ACKNOWLEDGE, START, STOP, and Repeated START bits.

For example, the host requests RemainingCapacity() from the bq2060A. This includes the host following the Read Word protocol. The bq2060A calculates the PEC based on the following 5 bytes of data, assuming the remaining capacity of the battery is 1001 mAh.

- Battery Address with $\overline{R/\overline{W}}$ = 0: 0x16
- Command Code for RemainingCapacity(): 0x0f
- Battery Address with $\overline{R/\overline{W}}$ = 1: 0x17
- RemainingCapacity(): 0x03e9

For 0x160f17e903, the bq2060A transmits a PEC of 0xe8 to the host.

PEC Enable in Master Mode

PEC for master mode broadcasts to the charger, host, or both can be enabled/disabled with the combination of the bits HPE and CPE in *Control Mode*.

SMBus On and Off State

The bq2060A detects whether the SMBus enters the Off State by monitoring the SMBC and SMBD lines. When both signals are continually low for at least 2.5 s, the bq2060A detects the Off State. When the SMBC and SMBD lines go high, the bq2060A detects the On State and can begin communication within 1 ms. One-M Ω pulldown resistors on SMBC and SMBD are recommended for reliable Off State detection.

HDQ16

The HDQ16 interface is a command-based protocol. (See [Figure 10](#).) A processor sends the command code to the bq2060A. The 8-bit command code consists of two fields, the 7-bit HDQ16 command code (bits 0–6) and the 1-bit $\overline{R/\overline{W}}$ field. The $\overline{R/\overline{W}}$ field directs the bq2060A either to

- Store the next 16 bits of data to a specified register or
- Output 16 bits of data from the specified register

With HDQ16, the least significant bit of a data byte (command) or word (data) is transmitted first.

A bit transmission consists of three distinct sections. The first section starts the transmission by either the host or the bq2060A taking the HDQ16 pin to a logic-low state for a period $t_{STRH;B}$. The next section is the actual data transmission, where the data bit is valid by the time, $t_{DSU;B}$ after the negative edge used to start communication. The data bit is held for a period $t_{DH;DV}$ to allow the host processor or bq2060A to sample the data bit.

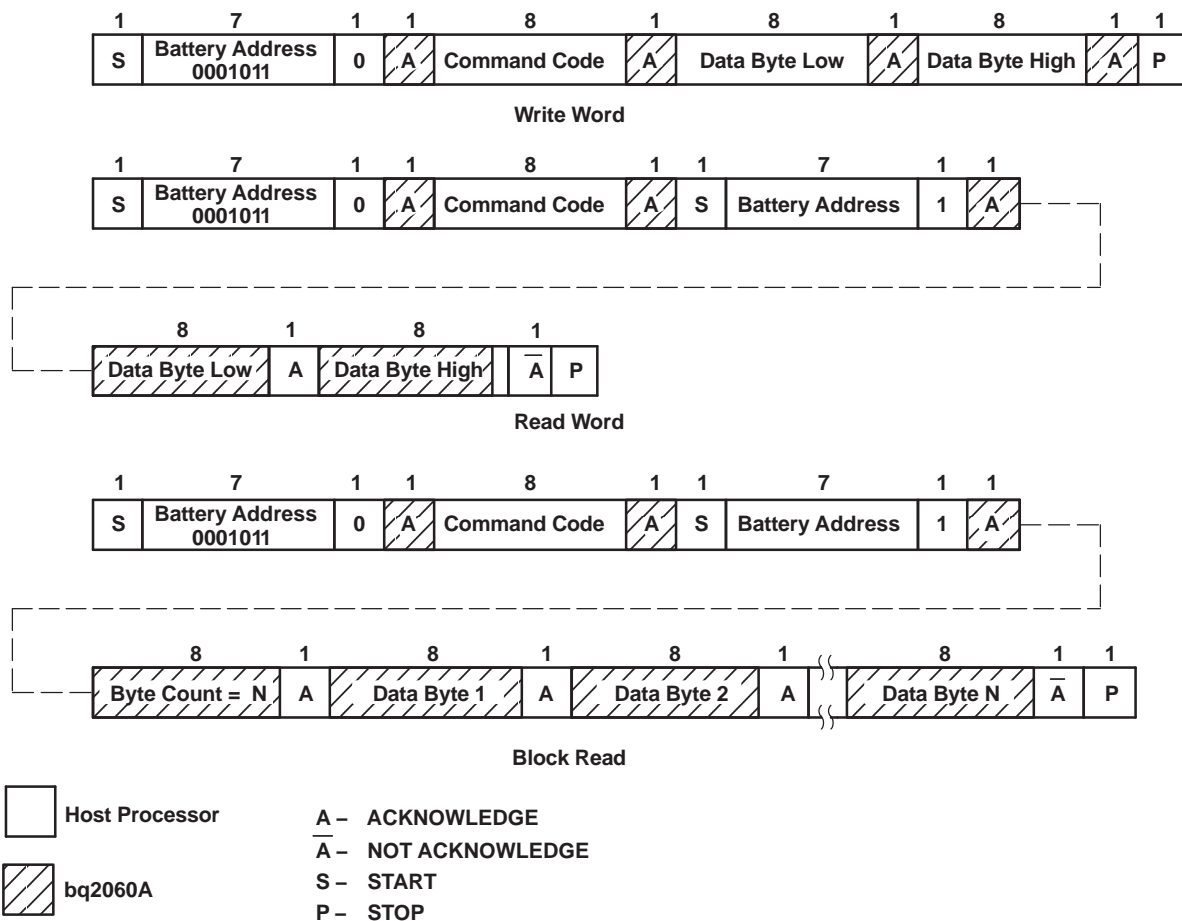


Figure 8. SMBus Communication Protocol without PEC

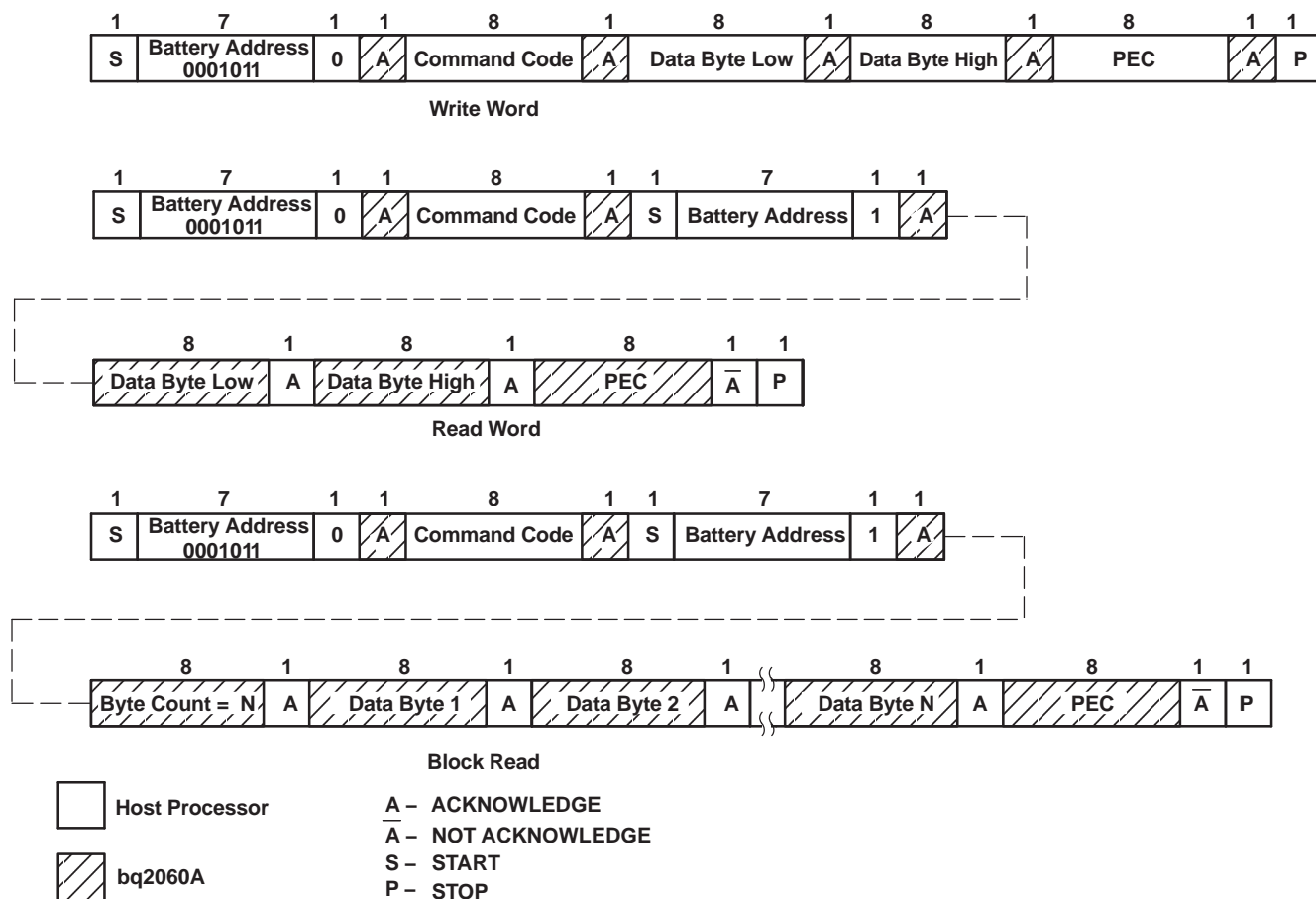


Figure 9. SMBus Communication Protocol with PEC

The final section is used to stop the transmission by returning the HDQ16 pin to a logic-high state by at least the time $t_{SSU:B}$ after the negative edge used to start communication. The final logic-high state should be until a period $t_{CYCH:B}$ to allow time to ensure that the bit transmission was stopped properly.

If a communication error occurs (e.g., $t_{CYCB} > 250 \mu s$), the host sends the bq2060A a BREAK to reinitiate the serial interface. The bq2060A detects a BREAK when the HDQ16 pin is in a logic-low state for a time t_B or greater. The HDQ16 pin is then returned to its normal ready-high logic state for a time t_{BR} . The bq2060A is then ready to receive a command from the host processor.

The HDQ16 pin is open drain and requires an external pullup resistor.

Command Codes

The SMBus Command Codes are in (), the HDQ16 in []. Temperature(), Voltage(), Current(), and AverageCurrent(), performance specifications are at regulated $V_{CC}(V_{RO})$ and a temperature of 0–70°C.

ManufacturerAccess() (0x00); [0x00–0x01]

Description: This function provides writable command codes to control the bq2060A during normal operation and pack manufacture. These commands can be ignored if sent within one second after a device reset. The following list of commands are available.

0x0618 Enable Low-Power Storage Mode: Activates the low-power storage mode. The bq2060A enters the storage mode after a 5-s to 8-s delay. The bq2060A accepts other commands to Manufacturer Access() during the delay before entering low-power storage mode. The LEDs must be off before entering the low-power storage mode as the display state remains unchanged. During the delay following the low-power storage command, a VFC Calibration command may be issued.

The bq2060A clears the ManufacturerAccess() command within 900 ms of acknowledging the Enable Low-Power Storage command. The VFC Calibration command may be sent 900–5000 ms after SMBus acknowledgment of the Enable Low-Power Storage command. In this case, the bq2060A delays entering storage mode until the calibration process completes and the bq2060A stores the new calibration values in EEPROM.

0x062b SEAL: Instructs the bq2060A to restrict access to those functions listed in Table 3. The bq2060A completes the seal function and clears ManufacturerAccess() within 900 ms of acknowledging the command.

0x064d Charge Synchronization: Instructs the bq2060A to update RM to a percentage of FCC as defined in *Fast Charge Termination %*. The bq2060A updates RM and clears Manufacturer Access() within 900 ms of acknowledging the command.

0x0653 Enable VFC Calibration: Instructs the unsealed bq2060A to begin VFC calibration. With this command, the bq2060A deselects the SR₁ and SR₂ inputs and calibrates for IC offset only. It is best to avoid charge or discharge currents through the sense resistor during this calibration process.

0x067e Alternate VFC Calibration: Instructs the unsealed bq2060A to begin VFC calibration. With this command, the bq2060A does not deselect the SR₁ and SR₂ inputs and does calibrate for IC and PCB offset. Any charge or discharge currents during this procedure result in an invalid VFC offset calibration and inaccurate VFC operation.

During VFC calibration, the bq2060A disables the LED display and accepts only the Stop VFC Calibration and the SEAL commands to ManufacturerAccess(). The bq2060A disregards all other commands. SMBus communication should be kept to a minimum during VFC calibration to reduce the noise level and allow a more accurate calibration.

Once started, the VFC calibration procedure completes automatically. When complete, the bq2060A saves the calibration values in EEPROM. The calibration normally takes about 8 to 10 minutes. The calibration time is inversely proportional to the bq2060A VFC (and PCB) offset error. The bq2060A caps the calibration time at one hour in the event of calibrating zero offset error. The VFC calibration can be done as the last step in a battery pack test procedure because the calibration can complete automatically after removal from a test setup.

The bq2060A clears ManufacturerAccess() within 900 ms and starts calibration within 3.2 s of acknowledging the command.

0x0660 Stop VFC Calibration: Instructs the bq2060A to abort a VFC calibration procedure. If aborted, the bq2060A disables offset correction. The bq2060A stops calibration within 20 ms of acknowledging the command.

0x0606 Program EEPROM: Instructs the unsealed bq2060A to connect the SMBus to the EEPROM I²C bus. The bq2060A applies power to the EEPROM within 900 ms of acknowledging the command. After issuing the program EEPROM command, the bq2060A monitoring functions are disabled until the I²C bus is disconnected. The bq2060A disconnects the I²C bus when it detects that the battery address 0x16 is sent over the SMBus. The battery address 0x16 to disconnect the I²C bus should not be sent until 10 ms after the last write to the EEPROM.

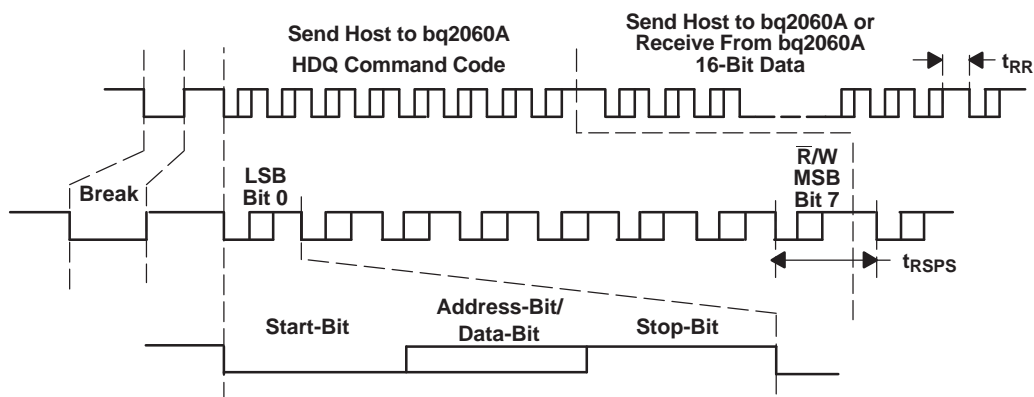


Figure 10. HDQ16 Communication Example

Example: The following sequence of actions is an example of how to use the ManufacturerAccess() commands in an efficient manner to take a battery pack that has completed all testing and calibration except for VFC calibration and to make it ready for shipment in the SEALED state and in low-power storage mode:

- Complete testing and calibration with desired final values stored in EEPROM. This process includes setting the SEAL bit in *Pack Configuration*. Sending a reset command to the bq2060A during test ensures that RAM values correspond to the final EEPROM values
- If the initial value of RemainingCapacity() must be non-zero, the desired value may be written to Command 0x26 with the pack unsealed. A reset sent after this step resets RM to zero.
- Issue the Enable Low-Power Storage Mode command.
- Within 900 ms to 1600 ms after sending the Enable Low-Power command, issue the Enable VFC Calibration command. This delays the low-power storage mode until after VFC calibration completion.
- Issue the SEAL Command subsequent to the VFC Calibration command. The bq2060A must receive the SEAL Command before VFC calibration completes. The bq2060A resets the OCE bit in Pack Status when calibration begins and sets the bit when calibration successfully completes.

After VFC calibration completes automatically, the bq2060A saves the VFC offset cancellation values in EEPROM and enters the low-power storage mode in about 20 s. In addition, the bq2060A is sealed, allowing access as defined in [Table 3](#) only.

Purpose: The ManufacturerAccess() function provides the system host access to bq2060A functions that are not defined by the SBD.

SMBus Protocol: Read or Write Word

Input/Output: Word

RemainingCapacityAlarm() (0x01); [0x01]

Description: Sets or gets the low-capacity threshold value. Whenever the RemainingCapacity() falls below the low-capacity value, the bq2060A sends AlarmWarning() messages to the SMBus Host with the REMAINING_CAPACITY_ALARM bit set. A low-capacity value of 0 disables this alarm. The bq2060A initially sets the low-capacity value to *Remaining Capacity Alarm* value programmed in EE 0x04–0x05. The low-capacity value remains unchanged until altered by the RemainingCapacityAlarm() function. The low-capacity value may be expressed in either current (mA) or power (10mWh) depending on the setting of the BatteryMode() CAPACITY_MODE bit.

Purpose: The RemainingCapacityAlarm() function can be used by systems that know how much power they require to save their operating state. It enables those systems to more finely control the point at which they transition into suspend or hibernate state. The low-capacity value can be read to verify the value in use by the bq2060 low-capacity alarm.

SMBus Protocol: Read or Write Word

Input/Output: Unsigned integer—value below which Low Capacity messages are sent.

BATTERY MODES		
	CAPACITY_MODE BIT = 0	CAPACITY_MODE BIT = 1
Units	mAh at C/5	10mWh at P/5
Range	0–65,535 mAh	0–65,535 10mWh
Granularity	Not applicable	
Accuracy	See RemainingCapacity()	

RemainingTimeAlarm() (0x02); [0x02]

Description: Sets or gets the remaining time alarm value. Whenever the AverageTimeToEmpty() falls below the remaining time value, the bq2060A sends AlarmWarning() messages to the SMBus Host with the REMAINING_TIME_ALARM bit set. A remaining time value of 0 effectively disables this alarm. The bq2060A initially sets the remaining time value to the *Remaining Time Alarm* value programmed in EE 0x02–0x03. The remaining time value remains unchanged until altered by the RemainingTimeAlarm() function.

Purpose: The RemainingTimeAlarm() function can be used by systems that want to adjust when the remaining time alarm warning is sent. The remaining time value can be read to verify the value in use by the bq2060 RemainingTimeAlarm().

SMBus Protocol: Read or Write Word

Input/Output:

Unsigned integer—the point below which remaining time messages are sent.

Units: minutes

Range: 0 to 65,535 minutes

Granularity: Not applicable

Accuracy: see AverageTimeToEmpty()

BatteryMode() (0x03); [0x03]

Description: This function selects the various battery operational modes and reports the battery mode and requests.

Defined modes include

- Whether the battery capacity information is specified in mAh or 10mWh (CAPACITY_MODE bit)
- Whether the ChargingCurrent() and ChargingVoltage() values are broadcast to the Smart Battery Charger when the bq2060A detects that the battery requires charging (CHARGER_MODE bit)
- Whether all broadcasts to the Smart Battery Charger and Host are disabled

The defined request condition is the battery requesting a conditioning cycle (RELEARN_FLAG).

Purpose:

The CAPACITY_MODE bit allows power management systems to best match their electrical characteristics with those reported by the battery. For example, a switching power supply represents a constant power load, whereas a linear supply is better represented by a constant current model. The CHARGER_MODE bit allows a SMBus Host or Smart Battery Charger to override the Smart Battery desired charging parameters by disabling the bq2060 broadcasts. The RE-LEARN_FLAG bit allows the bq2060A to request a conditioning cycle.

SMBus Protocol: Read or Write Word

Input/Output:

Unsigned integer—bit mapped (see the following).

Units: not applicable

Range: 0–1

Granularity: not applicable

Accuracy: not applicable

The BatteryMode() word is divided into two halves, the most significant bit (bits 8–15), which is read/write and the least significant bit (bits 0–7), which is read only. The bq2060A forces bits 0–6 to zero and prohibits writes to bit 7.

[Table 9](#) summarizes the meanings of the individual bits in the BatteryMode() word and specifies the default values, where applicable, are noted.

INTERNAL_CHARGE_CONTROLLER bit is not used by the bq2060A.

PRIMARY_BATTERY_SUPPORT bit is not used by the bq2060A.

RELEARN_FLAG bit set indicates that the bq2060A is requesting a capacity relearn cycle for the battery. The bq2060A sets the RELEARN_FLAG under any of three conditions: full reset, detection of 20 cycle counts without an FCC update, or a midrange voltage correction. The bq2060A clears this flag after a learning cycle has been completed.

CHARGE_CONTROLLER_ENABLED bit is not used by the bq2060A. The bq2060A forces this bit to zero.

PRIMARY_BATTERY bit is not used by the bq2060A. The bq2060A forces this bit to zero.

Table 9. Battery Mode Bits and Values

Battery Mode() Bits	Bits Used	Format	Allowable Values
INTERNAL_CHARGE_CONTROLLER	0	Read only bit flag	
PRIMARY_BATTERY_SUPPORT	1	Read only bit flag	
Reserved	2–6		
RELEARN_FLAG	7	Read only bit flag	0—Battery OK 1—Relearn cycle requested
CHARGE_CONTROLLER_ENABLED	8	R/W bit flag	
PRIMARY_BATTERY	9	R/W bit flag	
Reserved	10–12		
ALARM_MODE	13	R/W bit flag	0—Enable alarm broadcast (default) 1—Disable alarm broadcast
CHARGER_MODE	14	R/W bit flag	0—Enable charging broadcast (default) 1—Disable charging broadcast
CAPACITY_MODE	15	R/W bit flag	0—Report in mA or mAh (default) 1—Report in 10mW or 10mWh

ALARM_MODE bit is set to disable the bq2060 ability to master the SMBus and send AlarmWarning() messages to the SMBus Host and the Smart Battery Charger. When set, the bq2060A does NOT master the SMBus, and AlarmWarning() messages are NOT sent to the SMBus Host and the Smart Battery Charger **for a period of no more than 65 s and no less than 45 s**. When cleared (default), the Smart Battery sends the AlarmWarning() messages to the SMBus Host and the Smart Battery Charger any time an alarm condition is detected.

- The bq2060A polls the ALARM_MODE bit at least every 150 ms. Whenever the **ALARM_MODE** bit is set, the bq2060A resets the bit and starts or restarts a 55-s (nominal) timer. After the timer expires, the bq2060A automatically enables alarm broadcasts to ensure that the accidental deactivation of broadcasts does not persist. To prevent the bq2060A from becoming a master on the SMBus, an SMBus host must therefore continually set this bit at least once per 50 s to keep the bq2060A from broadcasting alarms.
- The ALARM_MODE bit defaults to a cleared state within 130 ms after the bq2060A detects the SMBus Off-State.
- The condition of the ALARM-MODE bit does NOT affect the operation or state of the CHARGER_MODE bit which is used to prevent broadcasts of ChargingCurrent() and ChargingVoltage() to the Smart Battery Charger.

CHARGER_MODE bit enables or disables the bq2060 transmission of ChargingCurrent() and ChargingVoltage() messages to the Smart Battery Charger. When set, the bq2060A does NOT transmit ChargingCurrent() and ChargingVoltage() values to the Smart Battery Charger. When cleared, the bq2060A transmits the ChargingCurrent() and ChargingVoltage() values to the Smart Battery Charger. The CHARGER_MODE bit defaults to a cleared state within 130 ms after the bq2060A detects the SMBus Off-State.

CAPACITY_MODE bit indicates if capacity information is reported in mA/mAh or 10mW/10mWh. When set, the bq2060A reports capacity information in 10mW/10mWh as appropriate. When cleared, the bq2060A reports capacity information in mA/mAh as appropriate. The CAPACITY_MODE bit defaults to a cleared state within 130 ms after the bq2060A detects the SMBus Off-State.

Note 1: The following functions are changed to accept or return values in mA/mAh or 10mW/10mWh depending on the CAPACITY_MODE bit:

- RemainingCapacityAlarm()
- AtRate()
- RemainingCapacity()
- FullChargeCapacity()
- DesignCapacity()

Note 2: The following functions are calculated on the basis of capacity and may be calculated differently depending on the CAPACITY_MODE bit:

- AtRateOK()
- AtRateTimeToEmpty()
- AtRateTimeToFull()

- RunTimeToEmpty()
- AverageTimeToEmpty()
- AverageTimeToFull()
- Remaining Time Alarm()
- BatteryStatus()

The bq2060A updates the non-AtRate related register values within 3 s of changing the state of the CAPACITY_MODE bit. The AtRate() values are updated after the next AtRate value is written to the bq2060A (or after the next 20 s scheduled refresh calculation).

AtRate() (0x04); [0x04]

Description: The AtRate() function is the first half of a two-function call-set used to set the AtRate value used in calculations made by the AtRateTimeToFull(), AtRateTimeToEmpty(), and AtRateOK() functions. The AtRate value may be expressed in either current (mA) or power (10mW) depending on the setting of the BatteryMode() CAPACITY_MODE bit.

Purpose: because the AtRate() function is the first half of a two-function call-set, it is followed by the second function of the call-set that calculates and returns a value based on the AtRate value and the present battery state. A delay of up to 1.3s is required after writing AtRate() before the bq2060A can acknowledge the requested AtRate function.

- When the AtRate() value is positive, the AtRateTimeToFull() function returns the predicted time to full charge at the AtRate value of charge.
- When the AtRate() value is negative, the AtRateTimeToEmpty() function returns the predicted operating time at the AtRate value of discharge.
- When the AtRate() value is negative, the AtRateOK() function returns a Boolean value that predicts the ability of the battery to supply the AtRate value of *additional* discharge energy (current or power) for 10 seconds.

The default value for AtRate() is zero. Writing AtRate() values over the HDQ16 serial port does NOT trigger a re-calculation of AtRateTimeToFull(), AtRateTimeToEmpty(), and AtRateOK() functions.

It is recommended that AtRate() requests should be limited to one request every 4 s.

SMBus Protocol: Read or Write Word

Input/Output: Signed integer—charge or discharge; the AtRate() value is positive for charge, negative for discharge, and zero for neither (default).

BATTERY MODE		
	CAPACITY_MODE BIT = 0	CAPACITY_MODE BIT = 1
Units	mA	10mW
Charge Range	1–32,767 mA	1–32,768 10mW
Discharge Range	–1 to –32,768 mA	–1 to –32,768 10mW
Granularity	1 unit	
Accuracy	NA	

AtRateTimeToFull() (0x05);[0x05]

Description: Returns the predicted remaining time to fully charge the battery at the AtRate() value (mA).

Purpose: The AtRateTimeToFull() function is part of a two-function call-set used to determine the predicted remaining charge time at the AtRate value in mA. The bq2060A updates AtRateTimeToFull() within 1.3 s after the SMBus Host sets the AtRate value. If read before this delay, the command is No Acknowledged and the error code in BatteryStatus is set to *not ready*. The bq2060A automatically updates AtRateTimeToFull() based on the AtRate() value every 20 s.

SMBus Protocol: Read Word

Output:

Unsigned integer—predicted time in minutes to fully charge the battery.

- Units: minutes
- Range: 0 to 65,534 min
- Granularity: 2 min or better
- Accuracy: $\pm \text{MaxError}() * \text{FullChargeCapacity}() / |\text{AtRate}()|$
- Invalid Data Indication: 65,535 indicates the battery is not being charged.

AtRateTimeToEmpty() (0x06); [0x06]

Description: Returns the predicted remaining operating time if the battery is discharged at the AtRate() value.

Purpose: The AtRateTimeToEmpty() function is part of a two-function call-set used to determine the remaining operating time at the AtRate() value. The bq2060A updates AtRateTimeToEmpty() within 1.3 s after the SMBus Host sets the AtRate() value. If read before this delay, the command is No Acknowledged, and the error code in BatteryStatus is set to *not ready*. The bq2060A automatically updates AtRateTimeToEmpty() based on the AtRate() value every 20 s.

SMBus Protocol: Read Word

Output:

Unsigned integer — estimated operating time left.

- Units: minutes
- Range: 0 to 65,534 min
- Granularity: 2 min or better
- Accuracy: $-0, +\text{MaxError}() * \text{FullChargeCapacity} / |\text{AtRate}()|$
- Invalid Data Indication: 65,535 indicates the battery is not being discharged.

AtRateOK() (0x07); [0x07]

Description: Returns a Boolean value that indicates whether or not the battery can deliver the AtRate() value of additional energy for 10 seconds (Boolean). If the AtRate value is zero or positive, the AtRateOK() function *always* returns true.

Purpose: The AtRateOK() function is part of a two-function call-set used by power management systems to determine if the battery can safely supply enough energy for an additional load. The bq2060A updates AtRateOK() within 1.3 s after the SMBus Host sets the AtRate() value. If read before this delay, the command is No Acknowledged, and the error code in BatteryStatus is set to *not ready*. The bq2060A automatically updates AtRateOK() based on the At Rate() value every 20 s.

SMBus Protocol: Read Word

Output:

Boolean—indicates if the battery can supply the *additional* energy requested.

- Units: Boolean
- Range: TRUE, FALSE
- Granularity: not applicable
- Accuracy: not applicable

Temperature() (0x08); [0x08]

Description: Returns the temperature (K) measured by the bq2060A.

Purpose: The Temperature() function provides accurate cell temperatures for use by battery chargers and thermal management systems. A battery charger can use the temperature as a safety check. Thermal management systems may use the temperature because the battery is one of the largest thermal sources in a system.

SMBus Protocol: Read Word

Output:

Unsigned integer—cell temperature in tenth-degree Kelvin increments.

- Units: 0.1°K
- Range: 240.4°K to 388.0°K
- Granularity: 0.1°K
- Accuracy: $\pm 1.5^\circ\text{K}$ (from ideal 103AT thermistor performance, after calibration from 0°K to 70°K)

Voltage() (0x09); [0x09]

Description: Returns the cell-pack voltage (mV).

Purpose: The Voltage() function provides power management systems with an accurate battery terminal voltage. Power management systems can use this voltage, along with battery current information, to characterize devices they control. This ability helps enable intelligent, adaptive power management systems.

SMBus Protocol: Read Word

Output:

Unsigned integer—battery terminal voltage in mV.

- Units: mV
- Range: 0 to 20,000 mV
- Granularity: 1 mV
- Accuracy: $\pm 0.65\%$ (after calibration)

Current() (0x0a); [0x0a]

Description: Returns the current being supplied (or accepted) through the battery terminals (mA).

Purpose: The Current() function provides a snapshot for the power management system of the current flowing into or out of the battery. This information is of particular use in power management systems because they can characterize individual devices and tune their operation to actual system power behavior.

SMBus Protocol: Read Word

Output:

Signed integer—charge/discharge rate in mA increments—positive for charge, negative for discharge.

- Units: mA
- Range: ($\pm 250 \text{ mV}/R_S$) mA
- Granularity: $0.038 \text{ mV}/R_S$ (integer value)
- Accuracy: $\pm 1 \text{ mV}/R_S$ (after calibration)

AverageCurrent() (0x0b); [0x0b]

Description: Returns a value that approximates a one-minute rolling average of the current being supplied (or accepted) through the battery terminals (mA). The AverageCurrent() function returns meaningful values during the first minute of battery operation.

Purpose: The AverageCurrent() function provides the average current flowing into or out of the battery for the power management system.

SMBus Protocol: Read Word

Output:

Signed integer—charge/discharge rate in mA increments—positive for charge, negative for discharge.

- Units: mA
- Range: ($\pm 250 \text{ mV}/R_S$) mA
- Granularity: $0.038 \text{ mV}/R_S$ (integer value)
- Accuracy: $\pm 1 \text{ mV}/R_S$ (after calibration)

MaxError() (0x0c); [0x0c]

Description: Returns the expected margin of error (%) in the state of charge calculation. For example, when MaxError() returns 10% and RelativeStateOfCharge() returns 50%, the Relative StateOfCharge() is more likely between 50% and 60%. The bq2060A sets MaxError() to 100% on a full reset. The bq2060A sets MaxError() to 2% on completion of a learning cycle, unless the bq2060A limits the learning cycle to the +512/-256-mAh maximum adjustment values. If the learning cycle is limited, the bq2060A sets MaxError() to 8% unless MaxError() was already below 8%. In this case MaxError() does not change. The bq2060A increments MaxError() by 1% after four increments of CycleCount() without a learning cycle.

If voltage-based corrections are applied to the coulomb counter, MaxError() is set to 25%.

Purpose: The MaxError() function has real value in two ways: first, to give the user a confidence level about the state of charge and second, to give the power management system information about how aggressive it should be, particularly as the battery nears the end of its life.

SMBus Protocol: Read Word

Output:

Unsigned integer—percent uncertainty for selected information.

- Units: %
- Range: 2% to 100%
- Granularity: 1%
- Accuracy: not applicable

RelativeStateOfCharge() (0x0d); [0x0d]

Description: Returns the predicted remaining battery capacity expressed as a percentage of FullChargeCapacity() (%).

Purpose: The RelativeStateOfCharge() function is used to estimate the amount of charge remaining in the battery relative to the last learned capacity.

SMBus Protocol: Read Word

Output:

Unsigned integer—percent of remaining capacity.

- Units: %
- Range: 0% to 100%
- Granularity: 1%
- Accuracy: -0, +MaxError()

AbsoluteStateOfCharge()(0x0e); [0x0e]

Description: Returns the predicted remaining battery capacity expressed as a percentage of DesignCapacity() (%). Note that AbsoluteStateOfCharge() can return values greater than 100%.

Purpose: The AbsoluteStateOfCharge() function is used to estimate the amount of charge remaining in the battery relative to the nominal or DesignCapacity().

SMBus Protocol: Read Word

Output:**RemainingCapacity() (0x0f); [0x0f]**

Description: Returns the predicted charge or energy remaining in the battery. The RemainingCapacity() value is expressed in either charge (mAh at a C/5 discharge rate) or energy (10mWh at a P/5 discharge rate) depending on the setting of the BatteryMode() CAPACITY_MODE bit.

Purpose: The RemainingCapacity() function returns the remaining battery capacity. This information is a numeric indication of remaining charge or energy given by the Absolute or Relative StateOfCharge() functions and may be in a better form for use by power management systems.

SMBus Protocol: Read Word
Output:

Unsigned integer—remaining charge in mAh or 10mWh.

BATTERY MODE		
	CAPACITY_MODE BIT = 0	CAPACITY_MODE BIT = 1
Units	mAh	10mWh
Range	0–65,535 mAh	0–65, 535 10mWh
Granularity	mAh	10mWh
Accuracy	–0, +MaxError()*FullChargeCapacity()	

FullChargeCapacity() (0x10); [0x10]

Description: Returns the predicted pack capacity when it is fully charged. The FullChargeCapacity() value is expressed in either current (mAh at a C/5 discharge rate) or power (10mWh at a P/5 discharge rate) depending on the setting of the BatteryMode() CAPACITY_MODE bit.

Purpose: The FullChargeCapacity() function provides the user with a means of understanding the tank size of their battery. This information, along with information about the original capacity of the battery, can be presented to the user as an indication of battery wear.

SMBus Protocol: Read Word
Output:

Unsigned integer—estimated full-charge capacity in mAh or 10mWh.

BATTERY MODE		
	CAPACITY_MODE BIT = 0	CAPACITY_MODE BIT = 1
Units	mAh	10mWh
Range	0–65,535 mAh	0–65,535 10mWh
Granularity	mAh	10mWh
Accuracy	–0, +MaxError()*FullChargeCapacity()	

RunTimeToEmpty() (0x11); [0x11]

Description: Returns the predicted remaining battery life at the present rate of discharge (minutes). The RunTimeToEmpty() value is calculated based on either current or power depending on the setting of the BatteryMode() CAPACITY_MODE bit.

Purpose: The RunTimeToEmpty() provides the power management system with information about the relative gain or loss in remaining battery life in response to a change in power policy. This information is NOT the same as the AverageTimeToEmpty(), which is not suitable to determine the effects that result from a change in power policy.

SMBus Protocol: Read Word
Output:

Unsigned integer—minutes of operation left.

- Units: minutes
- Range: 0 to 65,534 min
- Granularity: 2 min or better
- Accuracy: –0, +MaxError()*FullChargeCapacity() / Current()
- Invalid Data Indication: 65,535 indicates battery is not being discharged.

AverageTimeToEmpty() (0x12); [0x12]

Description: Returns a 1-minute rolling average of the predicted remaining battery life (minutes). The AverageTimeToEmpty() value is calculated based on either current or power depending on the setting of the BatteryMode() CAPACITY_MODE bit.

Purpose: The AverageTimeToEmpty() displays state-of-charge information in a more useful way. It averages the instantaneous estimations so that the remaining time does not appear to jump around.

SMBus Protocol: Read Word

Output:

Unsigned integer—minutes of operation left.

- Units: minutes
- Range: 0 to 65,534 min
- Granularity: 2 min or better
- Accuracy: $-0, +\text{MaxError()} * \text{FullChargeCapacity()} / \text{AverageCurrent}()$
- Invalid Data Indication: 65,535 indicates battery is not being discharged.

AverageTimeToFull() (0x13); [0x13]

Description: Returns a 1-minute rolling average of the predicted remaining time until the battery reaches full charge (minutes).

Purpose: The AverageTimeToFull() function can be used by the SMBus host power-management system to aid in its policy. It may also be used to find out how long the system must be left on to achieve full charge.

SMBus Protocol: Read Word

Output:

Unsigned integer—remaining time in minutes.

- Units: minutes
- Range: 0 to 65,534 minutes
- Granularity: 2 minutes or better
- Accuracy: $\text{MaxError()} * \text{FullChargeCapacity()} / \text{AverageCurrent}()$
- Invalid Data Indication: 65,535 indicates the battery is not being charged

ChargingCurrent() (0x14); [0x14]

Description: Returns the desired charging rate in mA.

Purpose: The ChargingCurrent() function sets the maximum charge current of the battery. The ChargingCurrent() value should be used in combination with the ChargingVoltage() value to set the charger operating point. Together, these functions permit the bq2060A to dynamically control the charging profile (current/voltage) of the battery. The bq2060A can effectively turn off a charger by returning a value of 0 for this function. The charger may be operated as a constant-voltage source above its maximum regulated current range by returning a ChargingCurrent() value of 65,535.

SMBus Protocol: Read Word

Output:

Unsigned integer—maximum charger output current in mA.

- Units: mA
- Range: 0 mA to 65,535 mA
- Granularity: 1 mA
- Accuracy: not applicable
- Invalid Data Indication: 65,535 indicates that a charger should operate as a voltage source outside its maximum regulated current range.

ChargingVoltage() (0x15); [0x15]

Description: Returns the desired charging voltage in mV.

Purpose: The ChargingVoltage() function sets the maximum charge voltage of the battery. The ChargingVoltage() value should be used in combination with the ChargingCurrent() value to set the charger operating point. Together, these functions permit the bq2060A to dynamically control the charging profile (current/voltage) of the battery. The charger may be operated as a constant-current source above its maximum regulated voltage range by returning a ChargingVoltage() value of 65,535.

SMBus Protocol: Write Word

Output:

Unsigned integer—charger output voltage in mV.

- Units: mV
- Range: 0 mV to 65,535 mV
- Granularity: 1 mV
- Accuracy: not applicable
- Invalid Data Indication: 65,535 indicates that the charger should operate as a current source outside its maximum regulated voltage range.

BatteryStatus()(0x16); [0x16]

Description: Returns the bq2060 status word (flags). Some of the BatteryStatus() flags (REMAINING_CAPACITY_ALARM and REMAINING_TIME_ALARM) are calculated based on either current or power depending on the setting of the BatteryMode() CAPACITY_MODE bit. This is important because use of the wrong calculation mode may result in an inaccurate alarm.

Purpose: The BatteryStatus() function is used by the power management system to get alarm and status bits, as well as error codes from the bq2060A. This is basically the same information broadcast to both the SMBus Host and the Smart Battery Charger by the AlarmWarning() function except that the AlarmWarning() function sets the Error Code bits all high before sending the data.

SMBus Protocol: Read Word

Input/Output:

Unsigned integer—Status Register with alarm conditions bit-mapped as follows:

ALARM BITS	
0x8000	OVER_CHARGED_ALARM
0x4000	TERMINATE_CHARGE_ALARM
0x2000	Reserved
0x1000	OVER_TEMP_ALARM
0x0800	TERMINATE_DISCHARGE_ALARM
0x0400	Reserved
0x0200	REMAINING_CAPACITY_ALARM
0x0100	REMAINING_TIME_ALARM
STATUS BITS	
0x0080	INITIALIZED
0x0040	DISCHARGING
0x0020	FULLY_CHARGED
0x0010	FULLY_DISCHARGED

ERROR CODES	
0x0007	Unknown Error
0x0006	BadSize
0x0005	Overflow/Underflow
0x0004	AccessDenied
0x0003	UnsupportedCommand
0x0002	ReservedCommand
0x0001	Busy
0x0000	OK

Alarm Bits

OVER_CHARGED_ALARM bit is set whenever the bq2060A detects that the battery is being charged beyond the Maximum Overcharge limit. This bit is cleared when the bq2060A detects that the battery is no longer being charged (i.e., the bq2060A detects discharge activity or no activity for the digital filter timeout periods). The digital filter timeout period (seconds) equates to 10 times the value shared in *Digital Filter* EE0x52.

TERMINATE_CHARGE_ALARM bit is set when the bq2060A detects that one or more of the battery charging parameters are out of range (e.g., its voltage, current, or temperature is too high) or when the bq2060A detects a primary charge termination. This bit is cleared when the parameter falls back into the allowable range, the termination condition ceases, or when the bq2060A detects that the battery is no longer being charged.

OVER_TEMP_ALARM bit is set when the bq2060A detects that the internal battery temperature is greater than or equal to the *MaxT* limit. This bit is cleared when the internal temperature falls back into the acceptable range.

TERMINATE_DISCHARGE_ALARM bit is set when the bq2060A detects $\text{Voltage}() \leq \text{EDV0}$, the CVUV bit in Pack Status is set (Li-ion cell voltage has dropped below the limit programmed in Cell Under / Over Voltage), or $\text{RemainingCapacity}() = 0$. The bit is cleared when $\text{Voltage}() > \text{EDV0}$ or CVUV bit is cleared, and $\text{RemainingCapacity}() > 0$.

REMAINING_CAPACITY_ALARM bit is set when the bq2060A detects that $\text{RemainingCapacity}()$ is less than that set by the $\text{RemainingCapacityAlarm}()$ function. This bit is cleared when the value set by the $\text{RemainingCapacityAlarm}()$ function is lower than $\text{RemainingCapacity}()$.

REMAINING_TIME_ALARM bit is set when the bq2060A detects that the estimated remaining time at the present discharge rate is less than that set by the $\text{RemainingTimeAlarm}()$ function. This bit is cleared when the value set by the $\text{RemainingTimeAlarm}()$ function is lower than the $\text{AverageTimeToEmpty}()$.

Status Bits

INITIALIZED bit is set when the bq2060A has detected a valid load of EEPROM. It is cleared when the bq2060A detects an improper EEPROM load.

DISCHARGING bit is set when the bq2060A determines that the battery is not being charged. This bit is cleared when the bq2060A detects that the battery is being charged.

FULLY_CHARGED bit is set when the bq2060A detects a primary charge termination or an overcharged condition. It is cleared when $\text{RelativeStateOfCharge}() \leq$ the programmed Fully Charged Clear % in EE 0x4c.

FULLY_DISCHARGED bit is set when $\text{Voltage}() \leq \text{EDV2}$ threshold, or $\text{RemainingCapacity}() < \text{Full Charge Capacity} * \text{BatteryLow\%}$. This bit is cleared when the $\text{Relative StateOfCharge}()$ is $\geq 20\%$.

ERROR CODES	DESCRIPTION
OK	The bq2060A processed the function code without detecting any errors.
Busy	The bq2060A is unable to process the function code at this time.
Reserved	The bq2060A detected an attempt to read or write to a function code reserved by this version of the specification. The bq2060A detected an attempt to access an unsupported optional manufacturer function code.
Unsupported	The bq2060A does not support this function code which is defined in this version of the specification.
AccessDenied	The bq2060A detected an attempt to write to a read-only function code.
Over/Underflow	The bq2060A detected a data overflow or underflow.
BadSize	The bq2060A detected an attempt to write to a function code with an incorrect data block.

ERROR CODES	DESCRIPTION
UnknownError	The bq2060A detected an unidentifiable error.

CycleCount()(0x17); [0x17]

Description: Returns the number of cycles the battery has experienced. The mAh value of each count is determined by programming the *Cycle Count Threshold* value in EE 0x3c–0x3d. The bq2060A saves the cycle count value to *Cycle Count* EE 0x0e–0x0f after an update to CycleCount().

Purpose: The CycleCount() function provides a means to determine the battery wear. It may be used to give advanced warning that the battery is nearing its end of life.

SMBus Protocol: Read Word

Output:

Unsigned integer—count of total charge removed from the battery over its life.

- Units: cycle
- Range: 0 to 65,534 cycles 65,535 indicates battery has experienced 65,535 or more cycles.
- Granularity: 1 cycle
- Accuracy: absolute count

DesignCapacity() (0x18); [0x18]

Description: Returns the theoretical or nominal capacity of a new pack. The DesignCapacity() value is expressed in either current (mAh at a C/5 discharge rate) or power, (10mWh at a P/5 discharge rate) depending on the setting of the BatteryMode() CAPACITY_MODE bit.

Purpose: The DesignCapacity() function is used by the SMBus host power management with FullChargeCapacity() to determine battery wear. The power management system may present this information to the user and also adjust its power policy as a result.

SMBus Protocol: Read Word

Output:

Unsigned integer—battery capacity in mAh or 10mWh.

BATTERY MODE		
	CAPACITY_MODE BIT = 0	CAPACITY_MODE BIT = 1
Units	mAh	10mWh
Range	0–65,535 mAh	0–65,535 10mWh
Granularity	Not applicable	
Accuracy	Not applicable	

DesignVoltage() (0x19); [0x19]

Description: Returns the theoretical voltage of a new pack (mV). The bq2060A sets DesignVoltage() to the value programmed in *Design Voltage* EE0x12–0x13.

Purpose: The DesignVoltage() function can be used to give additional information about a particular Smart Battery's expected terminal voltage.

SMBus Protocol: Read Word

Output:

Unsigned integer—the battery's designed terminal voltage in mV

- Units: mV
- Range: 0 mV to 65,535 mV
- Granularity: not applicable

- Accuracy: not applicable

SpecificationInfo() (0x1a); [0x1a]

Description: Returns the version number of the Smart Battery specification that the battery pack supports, as well as voltage and current scaling information in a packed unsigned integer. Power scaling is the product of the voltage scaling times the current scaling. The SpecificationInfo is packed in the following fashion:

- $(\text{SpecID_H} * 0x10 + \text{SpecID_L}) + (\text{VScale} + \text{IPScale} * 0x10) * 0x100$

The bq2060A VScale (voltage scaling) and IPScale (current scaling) should always be set to zero. The bq2060A sets SpecificationInfo() to the value programmed in *Specification Information* EE 0x14–0x15.

Purpose: The SpecificationInfo() function is used by the SMBus host power-management system to determine what information the Smart Battery can provide.

SMBus Protocol: Read Word

Output:

Unsigned integer—packed specification number and scaling information.

FIELD	BITS USED	FORMAT	ALLOWABLE VALUES
SpecID_L	0...3	4-bit binary value	0–15
SpecID_H	4...7	4-bit binary value	0–15
VScale	8...11	4-bit binary value	0 (multiplies voltage by 10^{VScale})
IPScale	12...15	4-bit binary value	0 (multiplies current by 10^{IPScale})

ManufactureDate() (0x1b); [0x1b]

Description: This function returns the date the cell pack was manufactured in a packed integer. The date is packed in the following fashion: $(\text{year} - 1980) \times 512 + \text{month} \times 32 + \text{day}$. The bq2060A sets ManufactureDate() to the value programmed in *Manufacture Date* EE 0x16–0x17.

Purpose: The ManufactureDate() provides the system with information that can be used to uniquely identify a particular battery pack when used with SerialNumber().

SMBus Protocol: Read Word

Output:

Unsigned integer—packed date of manufacture.

FIELD	BITS USED	FORMAT	ALLOWABLE VALUES
Day	0...4	5-bit binary value	0–31 (corresponds to date)
Month	5...8	4-bit binary value	1–12 (corresponds to month number)
Year	9...15	7-bit binary value	0–127 (corresponds to year biased by 1980)

SerialNumber() (0x1c); [0x1c]

Description: This function is used to return a serial number. This number, when combined with the ManufacturerName(), the DeviceName(), and the ManufactureDate(), uniquely identifies the battery (unsigned integer). The bq2060A sets SerialNumber() to the value programmed in *Serial Number* EE 0x18–0x19.

Purpose: The SerialNumber() function can be used to identify a particular battery. This may be important in systems that are powered by multiple batteries where the system can log information about each battery that it encounters.

SMBus Protocol: Read Word

Output: Unsigned integer

ManufacturerName() (0x20); [0x20–0x2a]

Description: This function returns a character array containing the battery manufacturer's name. For example, MyBattCo would identify the Smart Battery manufacturer as MyBattCo. The bq2060A sets ManufacturerName() to the value programmed in *Manufacturer Name* EE 0x20–0x2a.

Purpose: The ManufacturerName() function returns the name of the Smart Battery manufacturer. The manufacturer's name can be displayed by the SMBus host power-management system display as both an identifier and as an advertisement for the manufacturer. The name is also useful as part of the information required to uniquely identify a battery.

SMBus Protocol: Read Block

Output:

String—character string with maximum length of 10 characters (10 + length byte).

DeviceName() (0x21); [0x28–0x2b]

Description: This function returns a character string that contains the battery name. For example, a DeviceName() of BQ2060A would indicate that the battery is a model BQ2060A. The bq2060A sets DeviceName() to the value programmed in *Device Name* EE 0x30–0x37.

Purpose: The DeviceName() function returns the battery name for identification purposes.

SMBus Protocol: Read Block

Output: String—character string with maximum length of 10 characters (10+length byte).

DeviceChemistry() (0x22); [0x30–0x32]

Description: This function returns a character string that contains the battery chemistry. For example, if the DeviceChemistry() function returns NiMH, the battery pack would contain nickel metal hydride cells. The bq2060A sets DeviceChemistry() to the value programmed in *Device Chemistry* EE 0x40–0x44.

Purpose: The DeviceChemistry() function gives cell chemistry information for use by charging systems. The bq2060A does not use DeviceChemistry() values for internal charge control or fuel gauging.

SMBus Protocol: Read Block

Output: String—character string with maximum length of 4 characters (4+length byte).

Lead acid	PbAc
Lithium ion	LION
Nickel cadmium	NiCd
Nickel metal hydride	NiMH
Nickel zinc	NiZn
Rechargeable alkaline-manganese	RAM
Zinc air	ZnAr

ManufacturerData() (0x23); [0x38–0x3a]

Description: This function allows access to the manufacturer data contained in the battery (data). The bq2060A stores seven critical operating parameters in this data area.

Purpose: The ManufacturerData() function may be used to access the manufacturer's data area. The data fields of this command reflect the programming of five critical EEPROM locations and can be used to facilitate evaluation bq2060A under various programming sets. The ManufacturerData() function returns the following information in order: *Control Mode*, *Digital Filter*, *Self-Discharge Rate*, *Battery Low %*, *Near Full*, and the pending EDV threshold voltage (low byte and high byte.)

SMBus Protocol: Read Block

Output: Block data—data that reflects EEPROM programming as assigned by the manufacturer with maximum length of 7 characters (7+length byte).

Pack Status and Pack Configuration (0x2f); [0x2f]

This function returns the Pack Status and Pack Configuration registers. The Pack Status register contains a number of status bits relating to bq2060A operation. The Pack Status register is the least significant byte of the word. The Pack Configuration register is the most significant byte of the word. The byte reflects how the bq2060A is configured as defined by the value programmed in *Pack Configuration* in EE 0x3f.

The Pack Status Register consists of the following bits:

b7	b6	b5	b4	b3	b2	b1	b0
OCE	EDV2	EINT	VDQ	COK	DOK	CVOV	CVUV

OCE

The OCE bit indicates that offset cancellation is enabled. The bq2060A sets this bit after VFC offset calibration is complete.

- 0 Offset calibration is not enabled
- 1 Offset calibration is enabled

EDV2

The EDV2 bit indicates that Voltage() is less than the EDV2 threshold.

- 0 Voltage() > EDV2 threshold (discharging)
- 1 Voltage() ≤ EDV2 threshold

EINT

The EINT bit indicates that the VFC has detected a charge or discharge pulse.

- 0 No charge/discharge activity detected
- 1 Charge/discharge activity detected.

VDQ

The VDQ bit indicates if the present discharge cycle is valid for an FCC update.

- 0 Discharge cycle is not valid
- 1 Discharge cycle is valid

COK

The COK bit indicates the status of the CFC pin of the bq2060A.

- 0 CFC pin is low
- 1 CFC pin is high

DOK

The DOK bit indicates the status of the DFC pin of the bq2060A.

- 0 DFC pin is low

- 1 DFC pin is high

CVOV

The CVOV bit indicates that a secondary Li-ion protection limit has been exceeded. It is set if any individual cell exceeds the programmed high voltage limit, if the pack voltage exceeds the overvoltage threshold, or if an overtemperature condition occurs. The bit is not latched and merely reflects the present overvoltage status.

- 0 No secondary protection limits exceeded
1 A secondary protection limit exceeded

CVUV

The CVUV bit indicates if any individual cell falls below the programmed low-voltage limit. The bit applies to lithium batteries only. The bit is not latched and merely reflects the present undervoltage status.

- 0 All series cells are above the low-voltage limit
1 A series cell is below the low-voltage limit

VCELL4–VCELL1 (0x3c–0x3f); [0x3c–0x3f]

These functions return the calculated voltages in mV at the VCELL₄ through VCELL₁ inputs.

EEPROM

General

The bq2060A accesses the external EEPROM during a full reset and when storing historical data. During an EEPROM access, the VOUT pin becomes active, and the bq2060A uses the ESCL and ESDA pins to communicate with the EEPROM. The EEPROM stores basic configuration information for use by the bq2060A. The EEPROM must be programmed correctly for proper bq2060A operation.

Memory Map

[Table 10](#) shows the memory map for the EEPROM. It also contains example data for a 10-series NiMH and a 3s3p Li-ion battery pack with a 0.05-Ω sense resistor.

EEPROM Programming

The following sections describes the function of each EEPROM location and how the data is to be stored.

Fundamental Parameters

Sense Resistor Value

Two factors are used to scale the current-related measurements. The 16-bit *ADC Sense Resistor Gain* value in EE 0x68–0x69 scales Current() to mA. Adjusting *ADC Sense Resistor Gain* from its nominal value provides a method to calibrate the current readings for system errors and the sense resistor value (R_S). The nominal value is set by

$$\text{ADC Sense Resistor Gain} = \frac{625}{(R_S)} \quad (4)$$

The 16-bit *VFC Sense Resistor Gain* in EE 0x6a–0x6b scales each VFC interrupt to mAh. *VFC Sense Resistor Gain* is based on the resistance of the series sense resistor. The following formula computes a nominal or starting value for *VFC Sense Resistor Gain* from the sense resistor value.

$$\text{VFC Sense Resistor Gain} = \frac{409.6}{(R_S)} \quad (5)$$

Sense resistor values are limited to the range of 0.00954 to 0.100 Ω.

Digital Filter

The digital filter threshold, VDF (μV), is set by the value stored in *Digital Filter* EE 0x52.

$$\text{Digital Filter} = \frac{2250}{\text{VDF}} \quad (6)$$

Cell Characteristics

Battery Pack Capacity and Voltage

Pack capacity in mAh units is stored in *Pack Capacity* EE 0x3a–0x3b. In mAh mode, the bq2060A copies *Pack Capacity* to *DesignCapacity()*. In mWh mode, the bq2060A multiplies *Pack Capacity* by *Design Voltage* EE 0x12–0x13 to calculate *DesignCapacity()* scaled to 10mWh. *Design Voltage* is stored in mV.

The initial value for *Last Measured Discharge* in mAh is stored in EE 0x38–0x39. *Last Measured Discharge* is modified over the course of pack usage to reflect cell aging under the particular use conditions. The bq2060A updates *Last Measured Discharge* in mAh after a capacity learning cycle. The bq2060A uses the *Last Measured Discharge* value to calculate *FullChargeCapacity()* in mAh or 10mWh mode.

Table 10. EEPROM Memory Map

EEPROM Address		Name	Chemistry	NiMH Example	Data		Li-Ion Example	Data	
					MSB	LSB		MSB	LSB
0x00	0x01	<i>Check Byte 1</i>	Li-Ion, nickel	15487	3c	7f	15487	3c	7f
0x02	0x03	<i>Remaining Time Alarm</i>	Li-Ion, nickel	10 minutes	00	0a	10 minutes	00	0a
0x04	0x05	<i>Remaining Capacity Alarm</i>	Li-Ion, nickel	350 mAh	01	5e	400 mAh	01	90
0x06		<i>EDV A0 Impedance Age Factor</i>	Li-Ion, nickel	0	—	00	0	—	00
0x07		<i>EDV TC Cold Impedance Factor</i>	—	0	—	00	3	—	03
0x08		<i>Misc Options</i>	—	0	—	00	0	—	00
0x09		<i>Safety Overtemperature</i>	—	0	—	00	0	—	00
0x0a	0x0b	<i>Charging Voltage</i>	Li-Ion, nickel	18000 mV	46	50	12600 mV	31	38
0x0c	0x0d	Reserved	—	128	00	80	128	00	80
0x0e	0x0f	<i>Cycle Count</i>	Li-Ion, nickel	0	00	00	0	00	00
0x10	0x11	Reserved	—	0	00	00	0	00	00
0x12	0x13	<i>Design Voltage</i>	Li-Ion, nickel	12000 mV	2e	e0	10800 mV	2a	30
0x14	0x15	<i>Specification Information</i>	Li-Ion, nickel	v1.1/PEC	00	31	v1.1/PEC	00	31
0x16	0x17	<i>Manufacture Date</i>	Li-Ion, nickel	2/25/99=9817	26	59	2/25/99=9817	26	59
0x18	0x19	<i>Serial Number</i>	Li-Ion, nickel	1	00	01	1	00	01
0x1a	0x1b	<i>Fast-Charging Current</i>	Li-Ion, nickel	4000 mA	0f	a0	3000 mA	0b	b8
0x1c	0x1d	<i>Maintenance Charging Current</i>	Li-Ion, nickel	200 mA	00	c8	0 mA	00	00
0x1e	0x1f	<i>Pre-Charge Current</i>	Li-Ion, nickel	800 mA	03	20	100 mA	00	64
0x20		<i>Manufacturer Name Length</i>	Li-Ion, nickel	9	—	09	9	—	09
0x21		<i>Character 1</i>	Li-Ion, nickel	B	—	42	B	—	42
0x22		<i>Character 2</i>	Li-Ion, nickel	E	—	45	E	—	45
0x23		<i>Character 3</i>	Li-Ion, nickel	N	—	4e	N	—	4e
0x24		<i>Character 4</i>	Li-Ion, nickel	C	—	43	C	—	43
0x25		<i>Character 5</i>	Li-Ion, nickel	H	—	48	H	—	48
0x26		<i>Character 6</i>	Li-Ion, nickel	M	—	4d	M	—	4d
0x27		<i>Character 7</i>	Li-Ion, nickel	A	—	41	A	—	41
0x28		<i>Character 8</i>	Li-Ion, nickel	R	—	52	R	—	52
0x29		<i>Character 9</i>	Li-Ion, nickel	Q	—	51	Q	—	51
0x2a		<i>Character 10</i>	Li-Ion, nickel	0	—	00	0	—	00
0x2b		<i>Light Discharge Current</i>	Li-Ion, nickel	0	—	00	0	—	00
0x2c	0x2d	Reserved	—	0	00	00	0	00	00

Table 10. EEPROM Memory Map (continued)

EEPROM Address	Name	Chemistry	NiMH Example	Data		Li-Ion Example	Data	
				MSB	LSB		MSB	LSB
0x2e 0x2f	Maximum Overcharge	Li-Ion, nickel	200 mAh	ff	38	256 mAh	ff	00
0x30	Device Name Length	Li-Ion, nickel	7	—	07	7	—	07
0x31	Character 1	Li-Ion, nickel	B	—	42	B	—	42
0x32	Character 2	Li-Ion, nickel	Q	—	51	Q	—	51
0x33	Character 3	Li-Ion, nickel	2	—	32	2	—	32
0x34	Character 4	Li-Ion, nickel	0	—	30	0	—	30
0x35	Character 5	Li-Ion, nickel	6	—	36	6	—	36
0x36	Character 6	Li-Ion, nickel	0	—	30	0	—	30
0x37	Character 7	Li-Ion, nickel	A	—	41	A	—	41
0x38 0x39	Last Measured Discharge	Li-Ion, nickel	4000 mAh	0f	a0	4050 mAh	0f	d2
0x3a 0x3b	Pack Capacity	Li-Ion, nickel	4000 mAh	0f	a0	4050 mAh	0f	d2
0x3c 0x3d	Cycle Count Threshold	Li-Ion, nickel	500 mAh	fe	0c	3240 mAh	f3	58
0x3e	Reserved	—	0	—	00	0	—	00
0x3f	Pack Configuration	Li-Ion, nickel	232	—	e8	246	—	f6
0x40	Device Chemistry Length	Li-Ion, nickel	4	—	04	4	—	04
0x41	Character 1	Li-Ion, nickel	N	—	4e	L	—	4c
0x42	Character 2	Li-Ion, nickel	I	—	49	I	—	49
0x43	Character 3	Li-Ion, nickel	M	—	4d	O	—	4f
0x44	Character 4	Li-Ion, nickel	H	—	48	N	—	4e
0x45	MaxT DeltaT	Li-Ion, nickel	50°C, 3°C	—	c7	50°C, 4.6°C	—	cf
0x46 0x47	Overload Current	Li-Ion, nickel	6000 mA	17	70	6000 mA	17	70
0x48	Overvoltage Margin	Li-Ion, nickel	0	—	00	800 mV	—	32
0x49	Overcurrent Margin	Li-Ion, nickel	512 mA	—	20	512 mA	—	20
0x4a	Reserved	Nickel	0	—	00	—	—	—
	Cell Under/Over Voltage	Li-Ion	—	—	—	118	—	76
0x4b	Fast Charge Termination %	Li-Ion, nickel	96%	—	a0	100%	—	9c
0x4c	Fully Charged Clear %	Li-Ion, nickel	90%	—	a6	95%	—	a1
0x4d	Charge Efficiency	Li-Ion, nickel	97%	—	el	100%	—	ff
0x4e	Current Taper Threshold	Li-Ion	—	—	—	200 mA	—	12
	DeltaT Time	Nickel	180 s	—	07	—	—	—
0x4f	Holdoff Time	Nickel	240 s	—	04	—	—	—
	Current Taper Qual Voltage	Li-Ion	—	—	—	128 mV	—	40
0x50	Manufacturers Data Length	Li-Ion, nickel	7	—	07	7	—	07
0x51	Control Mode	Li-Ion, nickel	4	—	04	4	—	04
0x52	Digital Filter	Li-Ion, nickel	50 µV	—	2d	50 µV	—	2d
0x53	Self-Discharge Rate	Li-Ion, nickel	1%	—	cb	0.21%	—	05
0x54	Battery Low %	Li-Ion, nickel	7%	—	12	7%	—	12
0x55	Near Full	Li-Ion, nickel	200 mAh	—	64	200 mAh	—	64
0x56 0x57	Reserved	—	0	—	00	0	—	00
0x58 0x59	Reserved	—	0	—	00	0	—	00
0x5a 0x5b	Reserved	—	0	—	00	0	—	00
0x5c 0x5d	Reserved	—	0	00	00	0	00	00
0x5e 0x5f	VFC Offset ⁽¹⁾	Li-Ion, nickel	0	00	00	0	00	00
0x60	VFC Offset ⁽¹⁾	Li-Ion, nickel	0	—	00	0	—	00

(1) Reserved locations must be set as shown. Locations marked with an asterisk are calibration values that can be adjusted for maximum accuracy. For these locations the table shows the appropriate default or initial setting.

Table 10. EEPROM Memory Map (continued)

EEPROM Address	Name	Chemistry	NiMH Example	Data		Li-Ion Example	Data	
				MSB	LSB		MSB	LSB
0x61	<i>Temperature Offset^{*(1)}</i>	Li-Ion, nickel	0	—	00	0	—	00
0x62	<i>ADC Offset^{*(1)}</i>	Li-Ion, nickel	0	—	00	0	—	00
0x63	<i>Cell 2 Calibration Factor^{*(1)}</i>	Li-Ion	—	—	—	0	—	00
	<i>Efficiency Temperature Compensation</i>	Nickel	0.25%	—	20	—	—	—
0x64	<i>Cell 3 Calibration Factor^{*(1)}</i>	Li-Ion	—	—	—	0	—	00
	<i>Efficiency Drop Off Percentage</i>	Nickel	96%	—	a0	—	—	—
0x65	<i>Cell 4 Calibration Factor^{*(1)}</i>	Li-Ion	—	—	—	0	—	00
	<i>Efficiency Reduction Rate</i>	Nickel	1%	—	50	—	—	—
0x66	0x67 <i>ADC Voltage Gain^{*(1)}</i>	Li-Ion, nickel	16 : 1	4e	20	16 : 1	4e	20
0x68	0x69 <i>ADC Sense Resistor Gain^{*(1)}</i>	Li-Ion, nickel	0.05 Ω	30	d4	0.05 Ω	30	d4
0x6a	0x6b <i>VFC Sense Resistor Gain^{*(1)}</i>	Li-Ion, nickel	0.05 Ω	20	00	0.05 Ω	20	00
0x6c	0x6d <i>VOC 25%</i>	Li-Ion, nickel	11500 mV	d3	14	10550 mV	d6	ca
0x6e	0x6f <i>VOC 50%</i>	Li-Ion, nickel	12500 mV	cf	2c	10750 mV	d6	02
0x70	0x71 <i>VOC 75%</i>	Li-Ion, nickel	13500 mV	cb	44	11200 mV	d4	40
0x72	0x73 <i>EDVF/EDV0</i>	Li-Ion, nickel	9500 mV	25	1c	10265 mV	28	19
0x74	0x75 <i>EMF/ EDV1</i>	Li-Ion, nickel	10000 mV	27	10	11550	2d	1e
0x76	0x77 <i>EDV T0 Factor</i>	Li-Ion, nickel	0	00	00	4475	11	7b
0x78	0x79 <i>EDV C1/C0 Factor/EDV2</i>	Li-Ion, nickel	10500 mV	29	04	C1 = 0 C0 = 235	00	eb
0x7a	0x7b <i>EDV R0 Factor</i>	Li-Ion, nickel	0	00	00	5350	14	e6
0x7c	0x7d <i>EDV R1 Factor</i>	Li-Ion, nickel	0	—	00	250	00	fa
0x7e	0x7f <i>Check Byte 2</i>	Li-Ion, nickel	42330	a5	5a	42330	a5	5a

EDV Thresholds and Near-Full Percentage

The bq2060A uses three pack voltage thresholds to provide voltage-based warnings of low battery capacity. The bq2060A uses the values stored in EEPROM for the EDV0, EDV1, and EDV2 values or calculates the three thresholds from a base value and the temperature, capacity, and rate adjustment factors stored in EEPROM. If EDV compensation is disabled then EDV0, EDV1, and EDV2 are stored directly in mV in EE 0x72–0x73, EE 0x74–0x75, and EE 0x78–0x79, respectively.

For capacity correction at EDV2, *Battery Low %* EE 0x54 can be set at a desired state-of-charge, STATEOFCHARGE%, in the range of 5 to 20%. Typical values for STATEOFCHARGE% are 7–12% representing 7–12% capacity.

$$\text{Battery Low \%} = \text{STATEOFCHARGE\%} \times 2.56 \quad (7)$$

The bq2060A updates FCC if a qualified discharge occurs from a near-full threshold to EDV2. The desired near-full threshold window, NFW (mAh), is programmed in *Near Full* in EE 0x55.

$$\text{Near Full} = \frac{\text{NFW}}{2} \quad (8)$$

EDV Discharge Rate and Temperature Compensation

If EDV compensation is enabled, the bq2060A calculates battery voltage to determine EDV0, EDV1, and EDV2 thresholds as a function of battery capacity, temperature, and discharge load. (See [Figure 11](#) and [Figure 12](#).)

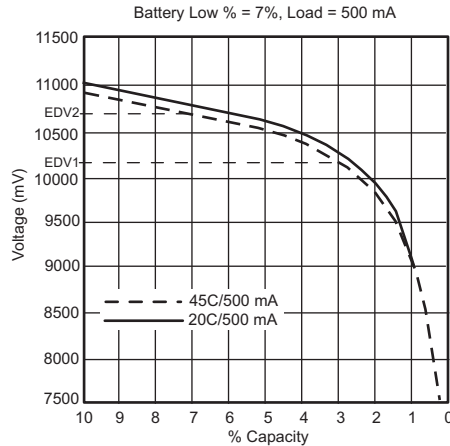


Figure 11. EDV Calculations vs Capacity for Various Temperatures

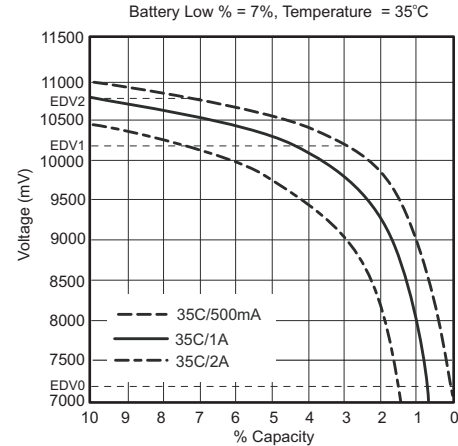


Figure 12. EDV Calculations vs Capacity for Various Loads

The general equation for EDV0, EDV1, and EDV2 calculation is

$$EDV_{0,1,2} = EMF \times F_{BL} - |I_{LOAD}| \times R_0 \times F_{TZ} \times F_{CY}$$

where

- EMF is a no-load battery voltage that is higher than the highest EDV threshold that is computed. EMF is programmed in mV in *EMF/EDV1 EE 0x74–0x75*.
- I_{LOAD} is the current discharge load.

(9)

F_{BL} is the factor that adjusts the EDV voltage for battery capacity and temperature to match the no-load characteristics of the battery.

$$F_{BL} = f(C_0, C + C_1, T)$$

(10)

where C (0%, 3%, or *Battery Low %* for EDV0, EDV1, and EDV2, respectively) and C_0 are the capacity-related EDV adjustment factors. C_0 is programmed in the lower 11 bits of *EDV C1/C0 Factor/EDV2 EE 0x78–79*.

The *Residual Capacity Factor* is stored in the upper 5 bits of *EE 0x78–0x79*.

Residual Capacity Factor $C_1 = \text{RESIDUAL\%} \times 2.56$.

RESIDUAL% is the desired battery capacity remaining at EDV0 (RM = 0).

- T is the current temperature in K

$R_0 \times F_{TZ}$ represents the resistance of the battery as a function of temperature and capacity.

$$F_{TZ} = f(R_1, T_0, T, C + C_1, TC)$$

(11)

- R_0 is the first-order rate dependency factor stored in *EDV R0 Factor EE 0x7a–0x7b*.
- T is the current temperature; C is the battery capacity relating to EDV0, EDV1, and EDV2; and C_1 is the desired residual battery capacity remaining at EDV0 (RM = 0).
- R_1 adjusts the variation of impedance with battery capacity. R_1 is programmed in *EDV R1 Factor EE 0x7c–0x7d*.
- T_0 adjusts the variation of impedance with battery temperature. T_0 is programmed in *EDV T0 Factor EE 0x76–0x77*.
- TC adjusts the variation of impedance for cold temperature ($T < 23^\circ\text{C}$). TC is programmed in *EDV TC EE 0x07*.

F_{CY} is the factor that adjusts for changing cell impedance as the battery pack is cycled:

$$F_{CY} = f(A_0, \text{Cycle Count}())$$

(12)

where A0 is the EDV aging factor that is stored in *EDV A0 Factor* EE 0x06. It should be set to 0 for most applications.

Typical values for the EDV compensation factors for a Li-ion 3s3p 18650 pack are

- EMF = 11550
- T0 = 4475
- C0 = 235
- C1 = 0
- R0 = 5350
- R1 = 250
- A0 = 0
- TC = 3

The graphs in Figures 7, 8, and 9 show the calculated EDV0, EDV1, and EDV2 thresholds versus capacity using the typical compensation values for different temperatures and loads for a Li-ion 3s3p 18650 pack. The compensation values vary widely for different cell types and manufacturers and must be matched exactly to the unique characteristics for optimal performance.

Overload Current Threshold

The *Overload Current* threshold is a 16-bit value stored in EE 0x46–0x47 in mA units.

Midrange Capacity Corrections

Three voltage-based thresholds, *VOC25* EE 0x6c–0x6d, *VOC50* EE 0x6e–0x6f, and *VOC75* EE 0x70–0x71, are used to test the accuracy of the RM-based on open-circuit pack voltages. These thresholds are stored in the EEPROM in 2s complement of voltage in mV. The values represent the open-circuit battery voltage at which the battery capacity should correspond to the associated state of charge for each threshold.

Self-Discharge Rate

The nominal self-discharge rate, %PERDAY (% per day), is programmed in an 8-bit value *Self-Discharge Rate* EE 0x53 by the following relation:

$$\text{Self-Discharge Rate} = 256 - \left(\frac{52.73}{\% \text{PERDAY}} \right) \quad (13)$$

If programmed to 0, then self-discharge accumulation is disabled.

Light-Load Current

The amount of light-load current in mA, ILEAK, used for compensation is stored in *Light Discharge Current* in EE 0x2b as follows:

$$\text{Light-Discharge Current} = \frac{\text{ILEAK} \times 1024}{45} \quad (14)$$

ILEAK is between 0.044 and 11.2 mA.

Charge Efficiency

The bq2060A uses four charge-efficiency factors to compensate for charge acceptance. These factors are coded in *Charge Efficiency* (EFF%), *Efficiency Reduction Rate* (ERR%), *Efficiency Drop Off Percentage* (EDOP%), and *Efficiency Temperature Compensation* (TEFF%).

The bq2060A applies the efficiency factor, EFF%, when *RelativeStateOfCharge()* is less than the value coded in *Efficiency Drop Off Percentage* EE 0x64. When *RelativeStateOfCharge()* is greater than or equal to the value coded in *Efficiency Drop Off Percentage*, EFF% and ERR% determine the charge efficiency rate. ERR% defines the percent efficiency reduction per percentage point of *RelativeStateOfCharge()* over *Efficiency Drop Off Percentage*. EFF% is encoded in *Charge Efficiency* EE 0x4d according to the following equation:

$$\text{Charge Efficiency} = 10 \times (\text{EFF\%} - 74.5) \quad (15)$$

where

$$74.5 \leq \text{EFF}\% \leq 100$$

ERR% is encoded in *Efficiency Reduction Rate* EE 0x65 according to the following equation:

$$\text{Efficiency Reduction Rate} = \frac{\text{ERR}\%}{0.0125}$$

where

$$\bullet \quad 0 \leq \text{ERR}\% \leq 3.19 \quad (16)$$

The *Efficiency Drop Off Percentage* is stored in 2s complement of percent.

The bq2060A also adjusts the efficiency factors for temperature. TEFF% defines the percent efficiency reduction per degree C over 25°C. TEFF% is encoded in *Efficiency Temperature Compensation* EE 0x63 according to the following equation:

$$\text{Efficiency Temperature Compensation} = \frac{\text{TEFF}\% \times 1.6}{0.0125}$$

where

$$\bullet \quad 0 \leq \text{TEFF}\% \leq 1.99 \quad (17)$$

The bq2060A applies all four charge-compensation factors when the CHEM bit in *Pack Configuration* is not set denoting a nickel pack.

$$\text{Effective Charge Efficiency (nickel only)} = \text{EFF}\% - \text{ERR}\%[\text{RSOC}() - \text{EDOP}\%] - \text{TEFF}\%[T(^{\circ}\text{C}) - 25^{\circ}\text{C}]$$

where

$$\bullet \quad \text{RSOC}() \geq \text{EFF}\% \text{ and } T \geq 25^{\circ}\text{C} \quad (18)$$

If CHEM is set denoting a Li-ion pack, the bq2060A applies only the value coded in *Charge Efficiency* and makes no other adjustments for charge acceptance.

Charge Limits and Termination Techniques

Charging Voltage

The 16-bit value, *Charging Voltage* EE 0x0a–0x0b programs the ChargingVoltage() value broadcast to a Smart Charger. It also sets the base value for determining overvoltage conditions during charging and voltage compliance during a constant-voltage charging methodology. It is stored in mV.

Overvoltage

The 8-bit value, *Overvoltage Margin* EE 0x48, sets the limit over ChargingVoltage() that is to be considered as an overvoltage charge-suspension condition. The voltage in mV above the ChargingVoltage(), VOVM, that should trigger a charge suspend is encoded in *Overvoltage Margin* as follows:

$$\text{Overvoltage Margin} = \frac{\text{VOVM}}{16}$$

where

$$\bullet \quad \text{VOVM is between 0 and 4080mV.} \quad (19)$$

Charging Current

ChargingCurrent() values are either broadcast to a Level 2 Smart Battery Charger or read from the bq2060A by a Level 3 Smart Battery Charger. The bq2060A sets the value of ChargingCurrent(), depending on the charge requirements and charge conditions of the pack.

When fast charge is allowed, the bq2060A sets ChargingCurrent() to the rate programmed in *Fast Charging Current* EE 0x1a–0x1b.

When fast charge terminates, the bq2060A sets ChargingCurrent() to zero and then to the *Maintenance Charging Current* EE 0x1c–0x1d when the termination condition ceases.

When Voltage() is less than EDV0, the bq2060A sets ChargingCurrent() to *Pre-charge Current* EE 0x1e–0x1f. Typically, this rate is larger than the maintenance rate to charge a deeply depleted pack up to the point where it may be fast charged.

Fast Charging Current, *Maintenance Charging Current*, and *Pre-Charge Current* are stored in mA.

Charge Suspension

During charge, the bq2060A compares the current to the ChargingCurrent() plus the value IOIM. If the pack is charged at a current above the ChargingCurrent() plus IOIM, the bq2060A sets ChargingCurrent() to zero to stop charging. IOIM is programmed in the EEPROM value, *Overcurrent Margin*, encoded as follows:

$$\text{Overcurrent Margin} = \frac{\text{IOIM}}{16} \quad (20)$$

Overcurrent Margin EE 0x49 may be used to program IOIM values of 0 to 4080 mA in 16-mA steps.

The desired temperature threshold for charge suspension, MAXTEMP, may be programmed between 45°C and 69°C in 1.6°C steps. Charge-suspension temperature is increased by 16° above the programmed value of MaxT if bit 5 in *Miscellaneous Option* EE 0x08 is set. *MaxT DeltaT* EE 0x45 (most significant nibble) is stored in a 4-bit value as shown:

$$\text{MaxT} = \left\lceil \frac{69 - \text{MAXTEMP}}{1.6} \right\rceil \quad (21)$$

The bq2060A suspends fast charge when fast charge continues past full by the amount programmed in *Maximum Overcharge* EE 0x2e–0x2f. *Maximum Overcharge* is programmed in 2s complement form of charge in mAh.

FULLY_CHARGED Bit Clear Threshold

The bq2060A clears the FULLY_CHARGED bit in BatteryStatus() when RelativeStateOfCharge() reaches the value, *Fully Charged Clear %* EE 0x4c. *Fully Charged Clear %* is an 8-bit value and is stored as a 2s complement of percent.

Fast Charge Termination Percentage

The bq2060A sets RM to a percentage of FCC on charge termination if the CSYNC bit is set in the Pack Configuration register. The percentage of FCC is stored in *Fast Charge Termination %* in EE 0x4b. The value is stored in 2s complement of percent.

Cycle Count Threshold

Cycle Count Threshold 0x3c–0x3d sets the number of mAh that must be removed from the battery to increment CycleCount(). *Cycle Count Threshold* is a 16-bit value stored in 2s complement of charge in mAh.

ΔT/ Δt Rate Programming

The ΔT portion of the ΔT/Δt rate is programmed in *DeltaT*, the low nibble of *MaxT DeltaT* EE 0x45 (least significant nibble). The Δ portion is programmed in *DeltaT Time* EE 0x4e.

$$\Delta T / \Delta t = \frac{[\text{DeltaT} \times 2 + 16] / 10}{[320 - \text{DeltaT} \times 20]} \left[\frac{^{\circ}\text{C}}{\text{s}} \right] \quad (22)$$

Table 11.

DeltaT	Δ(°C)	DeltaT_Time	t (s)
0	1.6	00	320
1	1.8	01	300
2	2.0	02	280

Table 11. (continued)

DeltaT	Δ(°C)	DeltaT_Time	t (s)
3	2.2	03	260
4	2.4	04	240
5	2.6	05	220
6	2.8	06	200
7	3.0	07	180
8	3.2	08	160
9	3.4	09	140
a	3.6	0a	120
b	3.8	0b	100
c	4.0	0c	80
d	4.2	0d	60
e	4.4	0e	40
f	4.6	0f	20

ΔT/Δt Holdoff Timer Programming

The holdoff timer is programmed in the lower nibble of *Holdoff Time* EE 0x4f. The holdoff time is 320 s minus 20 times the *Holdoff Time* value.

<i>Holdoff Time</i>	Holdoff Time (s)	<i>Holdoff Time</i>	Holdoff Time (s)
00	320	08	160
01	300	09	140
02	280	0a	120
03	260	0b	100
04	240	0c	80
05	220	0d	60
06	200	0e	40
07	180	0f	20

Current Taper Termination Characteristics

Two factors in the EEPROM set the current taper termination for Li-ion battery packs. The two coded locations are *Current Taper Qual Voltage* EE 0x4f and *Current Taper Threshold* EE 0x4e. Current taper termination occurs during charging when the pack voltage is above the charging voltage minus CELLV (mV) and the charging current is below the threshold coded in *Current Taper Threshold* for at least 80 s.

$$\text{Current Taper Qual Voltage} = \frac{\text{CELLV}}{2} \quad (23)$$

$$\text{Current TaperThreshold} = \frac{R_s \times i}{0.5025} \quad (24)$$

where i = the desired current termination threshold in mA, and R_s = VFC sense resistor in ohms.

PACK OPTIONS

Pack Configuration

Pack Configuration EE 0x3f contains bit-programmable features.

b7	b6	b5	b4	b3	b2	b1	b0
DMODE	SEAL	CSYNC	CEDV	VCOR	CHEM	LCC1	LCC0

DMODE

The DMODE bit determines whether the LED outputs will indicate AbsoluteStateOfCharge() or RelativeStateOfCharge()

- 0 LEDs reflect AbsoluteStateOfCharge()
- 1 LEDs reflect RelativeStateOfCharge()

SEAL

The SEAL bit determines the SMBus access state of the bq2060A on reset

- 0 SMBus commands (0x00–0xff) are accessible for both read and write.
- 1 SMBus read access is limited to commands (0x05–0x1c) and (0x20–0x23). SMBus read/write access is limited to commands (0x00–0x04), (0x2f), and (0x3c–0x3f).

CSYNC

In usual operation of the bq2060A, the CSYNC bit is set so that the coulomb counter is adjusted when a fast charge termination is detected. In some applications, especially those where an externally controlled charger is used, it may be desirable NOT to adjust the coulomb counter. In these cases the CSYNC bit should be cleared.

- 0 The bq2060A does not alter RM at the time of a valid charge termination.
- 1 The bq2060A updates RM with a programmed percentage of FCC at a valid charge termination.

CEDV

The CEDV bit determines whether the bq2060A implements automatic EDV compensation to calculate the EDV0, EDV1, and EDV2 thresholds base on rate, temperature, and capacity. If reset, the bq2060A uses the fixed values programmed in EEPROM for EDV0, EDV1 and EDV2. If set, the bq2060A calculates EDV0, EDV1, and EDV2.

- 0 EDV compensation disabled
- 1 EDV compensation enabled

VCOR

The VCOR bit enables the midrange voltage correction algorithm. When set, the bq2060A compares the pack voltage to RM and may adjust RM according to the values programmed in VOC25, VOC50, and VOC75.

- 0 Midrange corrections disabled
- 1 Midrange corrections enabled

CHEM

The CHEM bit configures the bq2060A for nickel packs (NiCd or NiMH) or Li-ion packs. When set, the bq2060A employs the configuration parameters in EEPROM designated for Li-ion. When not set, the bq2060A employs the configuration parameters designated for nickel.

- 0 The bq2060A uses nickel configuration parameters.
- 1 The bq2060A uses Li-ion configuration parameters.

LCC0 and LCC1

The LCC0 and LCC1 bits configure the cell voltage inputs (VCELL_{1–4}).

NO. OF SERIES CELLS	LCC1, LCC0	CELL VOLTAGE INPUTS
NA	00	VCELL ₄ = Cell Stack
2	01	VCELL ₁ = Cell 1 VCELL ₂ = Cell 2
3	10	VCELL ₁ = Cell 1
		VCELL ₂ = Cell 2
		VCELL ₃ = Cell 3
4	11	VCELL ₁ = Cell 1
		VCELL ₂ = Cell 2
		VCELL ₃ = Cell 3
		VCELL ₄ = Cell 4

For Li-ion packs with individual measurements, LCC0 and LCC1 define the number of series elements and their voltage measurement inputs. In each case (2, 3, or 4), the bq2060A uses the highest numbered cell voltage input to measure the pack voltage measurement as returned with Voltage(). For nickel chemistries or Li-ion without single-cell measurements, LCC0 and LCC1 must be set to 00. VCELL₄ is the pack voltage input for this programming.

Remaining Time and Capacity Alarms

Remaining Time Alarm in EE 0x02–0x03 and *Remaining Capacity Alarm* in 0x04–0x05 set the alarm thresholds used in the SMBus command codes 0x01 and 0x02, respectively. *Remaining Time Alarm* is stored in minutes and *Remaining Capacity Alarm* in mAh.

Secondary Protection Limits for Li-Ion

The cell undervoltage (V_{UV}) and overvoltage (V_{OV}) limits are programmed in *Cell Undervoltage/Over Voltage* EE 0x4a according to the equations:

$$\text{Cell Undervoltage/Overvoltage (lower)} = \frac{V_{OV} - 4096}{32} \quad (25)$$

$$\text{Cell Undervoltage/Overvoltage (upper)} = \frac{V_{OV} - 2048}{64} \quad (26)$$

CELL UNDER/OVERVOLTAGE (upper nibble)	V _{UV} (mV)	CELL UNDER/OVERVOLTAGE (lower nibble)	V _{OV} (mV)
0	2048	0	4096
1	2112	1	4128
2	2176	2	4160
3	2240	3	4192
4	2304	4	4224
5	2368	5	4256
6	2432	6	4288
7	2496	7	4320
8	2560	8	4352
9	2624	9	4384
a	2688	a	4416
b	2752	b	4448
c	2816	c	4480
d	2880	d	4512
e	2944	e	4544
f	3008	f	4576

Safety Overtemperature EE 0x09 sets Safety Overtemperature Threshold (SOT) level for the CFC pin. It can be programmed for a threshold of 69°C to 94.5°C. This range is increased by 16°C if *Miscellaneous Options* bit 5 = 1.

$$\text{Safety Overtemperature} = (94.5 - \text{SOT}) * 10$$

if *Miscellaneous Options* bit 5 = 0.

$$\text{Safety Overtemperature} = (110.5 - \text{SOT}) * 10$$

if *Miscellaneous Options* bit 5 = 1.

Miscellaneous Options

Miscellaneous Options EE 0x08 contains bit-programmable options. Bits 0–4 should be programmed to zero.

b7	b6	b5	b4	b3	b2	b1	b0
NE1	SOT	HIT	0	0	0	0	0

NE1

The NE1 bit disables the EDV1 threshold.

- 0 EDV1 enabled
- 1 EDV1 disabled

SOT

The SOT bit controls override of the CFC pin for Safety Overtemperature threshold.

- 0 CFC control with overvoltage, maximum temperature, and safety overtemperature.
- 1 CFC control; only with safety overtemperature.

HIT

The HIT bit controls the available temperature range for maximum temperature and Safety Overtemperature.

- 0 Maximum temperature set in normal 45°C–69°C range and Safety Overtemperature is 69°C – 94.5°C.
- 1 Maximum temperature set in elevated 61°C–85°C range and Safety Overtemperature is 85°C – 110.5°C.

Cycle Count Initialization

Cycle Count EE 0x0e–0x0f stores the initial value for the CycleCount() function. It should be programmed to 0x0000.

Control Modes

Control Mode EE0x51 contains additional bit programmable features.

b7	b6	b5	b4	b3	b2	b1	b0
NDF	—	HPE	CPE	LED	SC	—	SM

NDF

The NDF bit disables the digital filter during discharge if the SMBC and SMBD lines are high.

- 0 Digital filter enabled all the time
- 1 Digital filter disabled if SMBC and SMBD are high

HPE

The HPE bit enables/disables PEC transmissions to the Smart Battery host for master mode alarm messages.

- 0 No PEC byte on alarm warning to host
- 1 PEC byte on alarm warning to host

CPE

The CPE bit enables/disables PEC transmissions to the Smart Battery Charger for master mode alarm messages.

- 0 No PEC byte on broadcasts to charger
- 1 PEC byte on broadcasts to charger

LED

The LED bit configures the bq2060A for 4- or 5-LED indication.

- 0 Selects the 5-LED indication mode
- 1 Selects the 4-LED indication mode

SC

The SC bit enables learning cycle optimization for a Smart Charger or independent charge.

- 0 Learning cycle optimized for independent charger
- 1 Learning cycle optimized for Smart Charger

SM

The SM bit enables/disables master mode broadcasts by the bq2060A.

- 0 Broadcasts to host and charger enabled
- 1 Broadcasts to host and charger disabled

If the SM bit is set, modifications to bits in BatteryMode() do not re-enable broadcasts.

MEASUREMENT CALIBRATION

ADC

To describe how the bq2060A calculates reported battery and individual cell voltages, the following abbreviations and designations are used:

- $V_{CELL1-4}$ = voltages at the input pins of the bq2060A
- VCELL1–4 = reported cell voltages
- V_{n1-4} = voltages at the different series nodes in the battery
- Voltage() = reported battery voltage
- V_{sr} = voltage across the sense resistor

The reported voltages measurements, Voltage() and VCELL1–4, may be calibrated by adjusting five 8- or 16-bit registers in EEPROM: *ADC Offset* in EE0x62, *ADC Voltage Gain* in EE 0x66–0x67, *Cell 2 Calibration Factor* in EE 0x63, *Cell 3 Calibration Factor* in EE 0x64, and *Cell 4 Calibration Factor* in EE 0x65.

The bq2060A first computes the node voltages Vn1, Vn2, Vn3, and Vn4. The node voltages are inputs to the voltage dividers to the VCELL₁ through VCELL₄ input pins of the bq2060A. The bq2060A computes node voltages to calculate the five reported voltages by the bq2060A: Voltage(), VCELL1, VCELL2, VCELL3, and VCELL4.

An *ADC Voltage Gain* factor of 20,000 is the nominal value when using the recommended cell-voltage division ratios of 16:1 on the VCELL₄ and VCELL₃ inputs and 8:1 on the VCELL₂ and VCELL₁ inputs. The bq2060A subtracts the voltage across the sense resistor from the measurements so that the reported voltages reflect the cell-stack voltages only.

The bq2060A compute the node voltages as follows:

$$Vn1 = \left[\frac{VCELL \times 32768}{1250} + \text{ADC Offset} \right] \times \left[\frac{\text{ADC Voltage Gain}}{65536} \right] \quad (27)$$

$$Vn2 = \left[\frac{VCELL \times 32768}{1250} + \text{ADC Offset} \right] \times \left[\frac{\text{ADC Voltage Gain} + 8 \times \text{Cell 2 CalibrationFactor}}{65536} \right] \quad (28)$$

$$Vn3 = \left[\frac{VCELL \times 32768}{1250} + \text{ADC Offset} \right] \times \left[\frac{\text{ADC Voltage Gain} + 8 \times \text{Cell 3 CalibrationFactor}}{65536} \right] \times \left[\frac{2}{65536} \right] \quad (29)$$

$$Vn4 = \left[\frac{VCELL \times 32768}{1250} + \text{ADC Offset} \right] \times \left[\frac{\text{ADC Voltage Gain} + 8 \times \text{Cell 4 CalibrationFactor}}{65536} \right] \times \left[\frac{2}{65536} \right] \quad (30)$$

Note: With LCC1 – LCC0 = 00, *Cell 4 Calibration Factor* = 0.

ADC Offset adjusts the ADC reading for voltage and current measurements. *ADC Offset* is a signed 8-bit value that cancels offset present in the circuit with no potential or current flow. *ADC Offset* is typically set between –20 and 20.

The bq2060A uses the computed node voltages to calculate the reported voltages. It does not compute reported cell voltages greater than the selected number of nodes. If no individual cell voltages are to be measured, LCC1 – LCC0 should be set to 00 and the top of the battery stack should be connected to a voltage divider to the VCELL4 input.

The bq2060A computes the reported voltages as follows:

- Voltage() = Vn4 (LCC1 – LCC0 = 11 or 00) – V_{sr}
- Voltage() = Vn3 (LCC1 – LCC0 = 10) – V_{sr}
- Voltage() = Vn2 (LCC1 – LCC0 = 01) – V_{sr}
- VCELL4 = Vn4 – Vn3
- VCELL3 = Vn3 – Vn2
- VCELL2 = Vn2 – Vn1
- VCELL1 = Vn1 – V_{sr}

Current

The bq2060A scales Current() to mA units by the 16-bit value *ADC Sense Resistor Gain* in EE 0x68–0x69. Adjusting *ADC Sense Resistor Gain* from its nominal value provides a method to calibrate the current readings for variances in the ADC gain, internal voltage reference, and sense resistor value. The bq2060A calculates Current() by

$$\text{Current} = \frac{[(\text{ADC Reading} + \text{ADC Offset}) \times \text{ADC Sense Resistor Gain}]}{16384} \quad (31)$$

The nominal value for *ADC Sense Resistor Gain* is given by [Equation 4](#).

VFC

To calibrate the coulomb counting measurement for VFC gain errors and sense resistor tolerance, the value of *VFC Sense Resistor Gain* EE 0x6a–0x6b may be adjusted from its nominal value.

The nominal value of *VFC Sense Resistor Gain* is given by [Equation 5](#).

The bq2060A VFC circuit can introduce a signal opposite in sign from that of the inherent device and circuit offset to cancel this error. The offset calibration routine is initiated with commands to `ManufacturerAccess()`.

The bq2060A calculates the offset with the calibration routine and stores the calibration value using the least 21 bits of *VFC Offset* in EE 0x5e–0x60.

The least 20 bits store the offset calibration value (OCV). The sign of the offset calibration value is positive if the 21st bit is 0.

$$\text{OCV} = \frac{0.6 \text{ V}}{\text{VFC Offset}_{19-0}} \quad (32)$$

Temperature

The bq2060A uses *Temperature Offset* in EE 0x61 to calibrate the `Temperature()` function for offset. The required offset adjustment, TOFF (C), sets *Temperature Offset* according to [Equation 33](#).

$$\text{Temperature Offset} = \text{TOFF} \times 10 \quad (33)$$

where $-12.8 \leq \text{TOFF} \leq 12.7$

CONSTANTS AND STRING DATA

EEPROM Constants

Check/Byte 1 EE 0x00–0x01 and *Check Byte 2* EE 0x7e–0x7f must be programmed to 0x3c7f and 0xa55a, respectively.

Specification Information

Specification Information EE 0x14–0x15 stores the default value for the `SpecificationInfo()` function. It is stored in EEPROM in the same format as the data returned by the `SpecificationInfo()`.

Manufacture Date

Manufacture Date EE 0x16–0x17 stores the default value for the `ManufactureDate()` function. It is stored in EEPROM in the same format as the data returned by the `ManufactureDate()`.

Serial Number

Serial Number EE 0x18–0x19 stores the default value for the `SerialNumber()` put Range function. It is stored in EEPROM in the same format as the data returned by the `SerialNumber()`.

Manufacturer Name Data

Manufacturer Name Length EE 0x20 stores the length of the desired string that is returned by the `ManufacturerName()` function. Locations EE 0x21–0x2a store the characters for `ManufacturerName()` in ASCII code.

Device Name Data

Device Name Length EE 0x30 stores the length of the desired string that is returned by the DeviceName() function. Locations EE 0x31–0x37 store the characters for DeviceName() in ASCII code.

Device Chemistry Data

Device Chemistry Length EE 0x40 stores the length of the desired string that is returned by the DeviceChemistry() function. Locations EE 0x41–0x44 store the characters for DeviceChemistry() in ASCII code.

Manufacturers Data Length

Manufacturers Data Length EE 0x50 stores the length of the desired number of bytes that is returned by the ManufacturersData() function. It should be set to 7.

REVISION HISTORY

Changes from Revision B (September 2005) to Revision C	Page
• Changed unit for I _{REG} from μ s to μ A	4
• Deleted V _{OUT} pin from application diagram, and added voltage connection to V _{CC} pin	8
• Modified sentence in Discharge Count Register section	12

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
BQ2060A-E619DBQ	ACTIVE	SSOP/ QSOP	DBQ	28	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
BQ2060A-E619DBQG4	ACTIVE	SSOP/ QSOP	DBQ	28	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
BQ2060A-E619DBQR	ACTIVE	SSOP/ QSOP	DBQ	28	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
BQ2060A-E619DBQRG4	ACTIVE	SSOP/ QSOP	DBQ	28	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

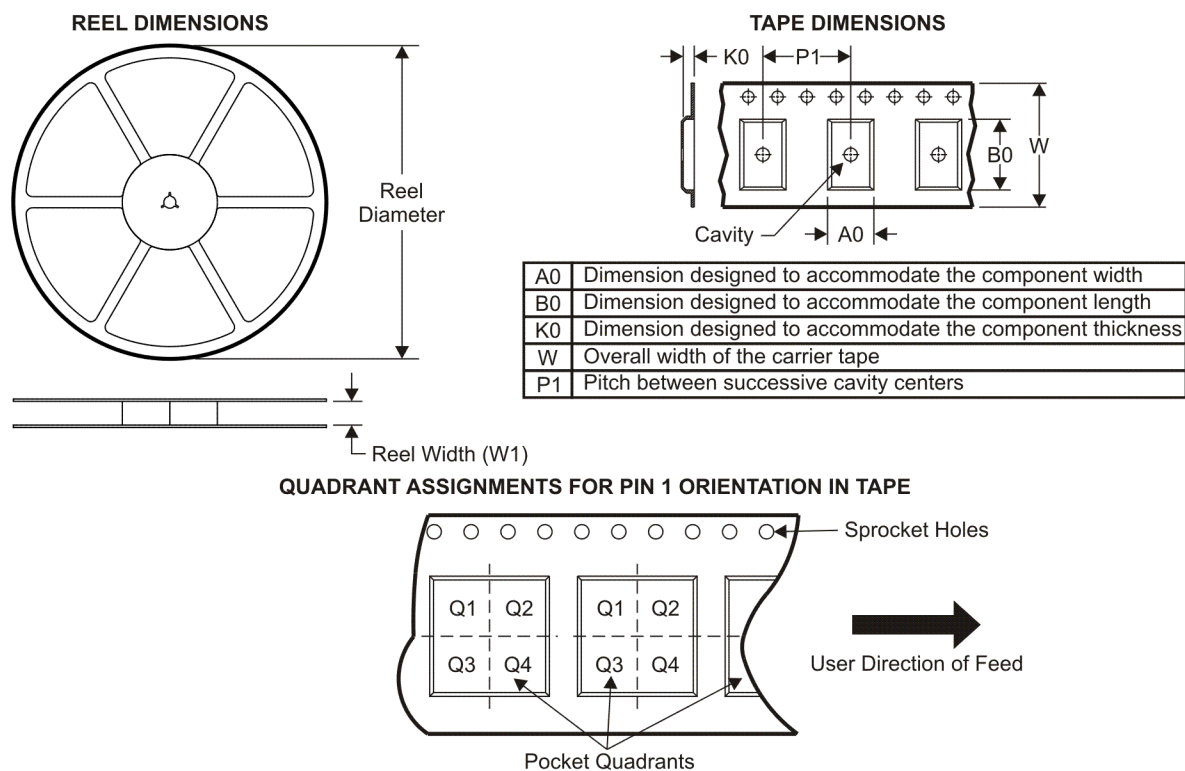
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
BQ2060A-E619DBQR	SSOP/QSOP	DBQ	28	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

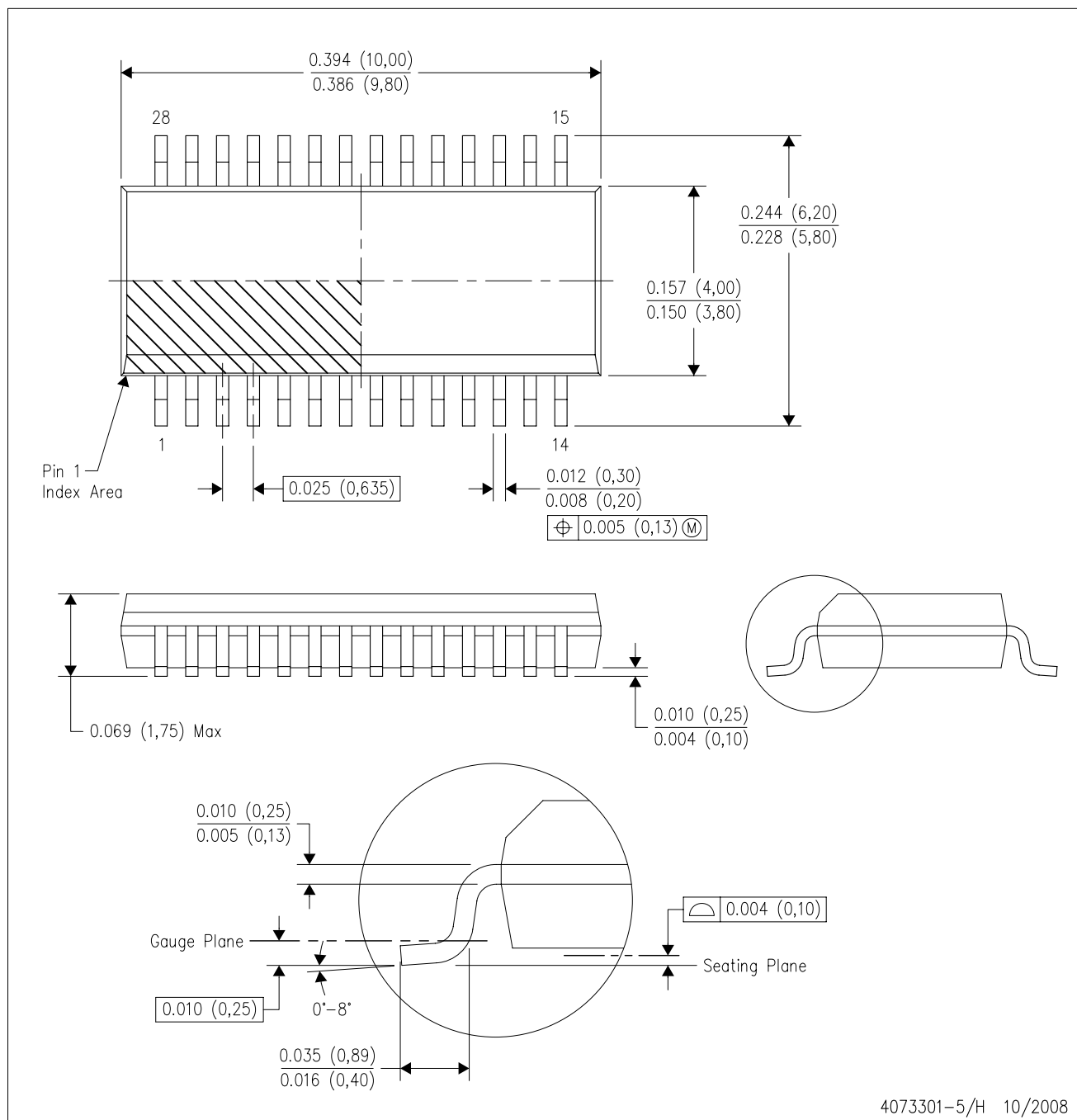


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ2060A-E619DBQR	SSOP/QSOP	DBQ	28	2500	346.0	346.0	33.0

DBQ (R-PDSO-G28)

PLASTIC SMALL-OUTLINE PACKAGE

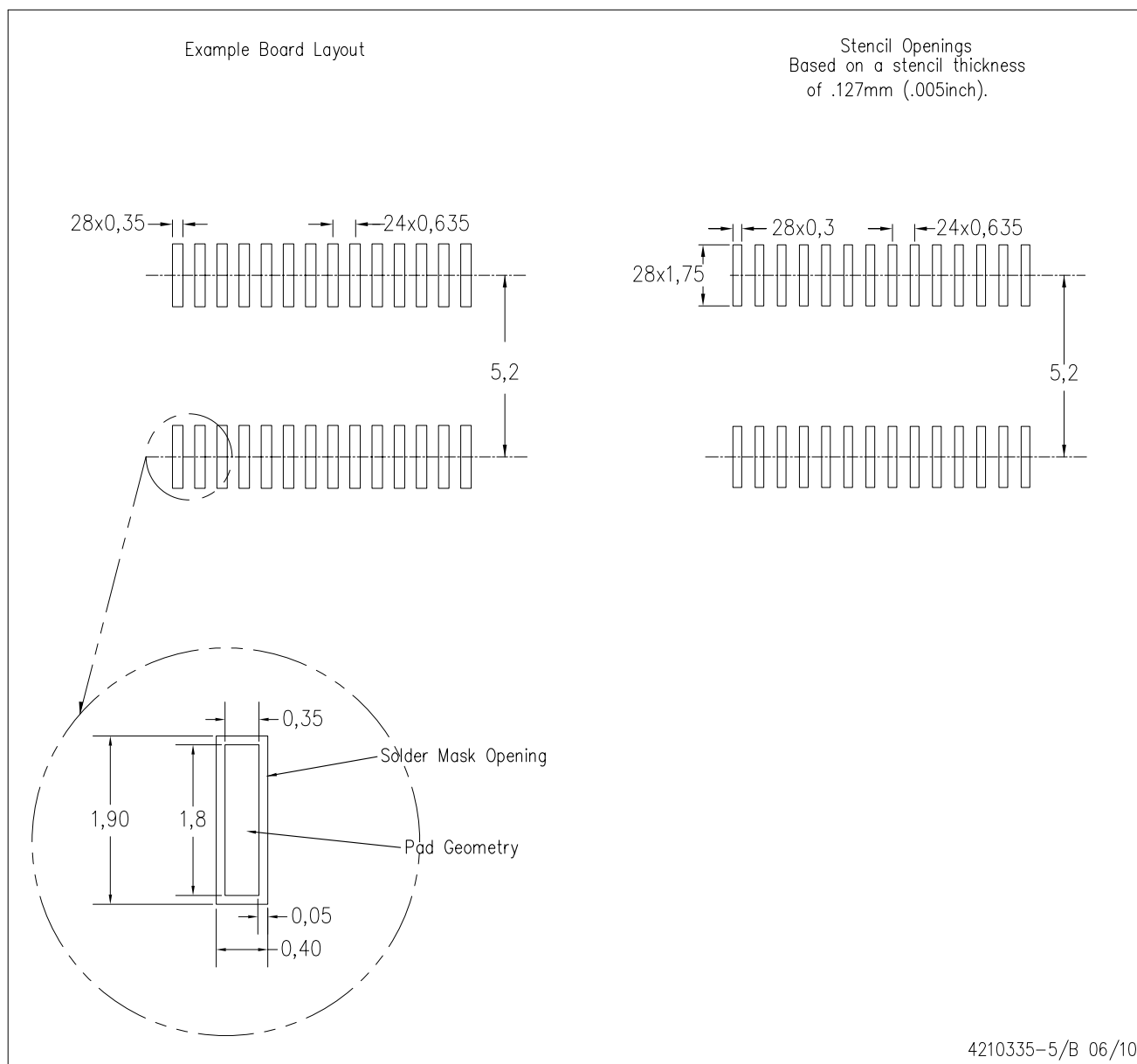


4073301-5/H 10/2008

- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
 - Falls within JEDEC MO-137 variation AF.

DBQ (R-PDSO-G28)

PLASTIC SMALL OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DLP® Products	www.dlp.com	Communications and Telecom	www.ti.com/communications
DSP	dsp.ti.com	Computers and Peripherals	www.ti.com/computers
Clocks and Timers	www.ti.com/clocks	Consumer Electronics	www.ti.com/consumer-apps
Interface	interface.ti.com	Energy	www.ti.com/energy
Logic	logic.ti.com	Industrial	www.ti.com/industrial
Power Mgmt	power.ti.com	Medical	www.ti.com/medical
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
RFID	www.ti-rfid.com	Space, Avionics & Defense	www.ti.com/space-avionics-defense
RF/IF and ZigBee® Solutions	www.ti.com/lprf	Video and Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless-apps